# **Intrinsic (Axion) Statistical Topological Insulator**

Xi Chen,<sup>1,\*</sup> Fa-Jie Wang,<sup>1,\*</sup> Zhen Bi,<sup>2</sup> and Zhi-Da Song<sup>1,3,4,†</sup>

<sup>1</sup>International Center for Quantum Materials, School of Physics, Peking University, Beijing 100871, China 
<sup>2</sup>Department of Physics, The Pennsylvania State University, University Park, Pennsylvania 16802, USA 

<sup>3</sup>Hefei National Laboratory, Hefei 230088, China 

<sup>4</sup>Collaborative Innovation Center of Quantum Matter, Beijing 100871, China 
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Ensembles that respect symmetries on average exhibit richer topological states than those in pure states with exact symmetries, leading to the concept of average symmetry-protected topological states (ASPTs). The freefermion counterpart of ASPT is the so-called statistical topological insulator (STI) in disordered ensembles. In this work, we demonstrate the existence of intrinsic STI - which has no band insulator correspondence characterized by the half-quantized magneto-electric polarization  $P_3 = \theta/(2\pi)$ . A  $C_4T$  symmetry reverses the sign of  $\theta$  angle, hence seems to protect a  $\mathbb{Z}_2$  classification of  $\theta = 0, \pi$ . However, we prove that, if  $(C_4T)^4 = 1$ , the topological state with  $\theta = \pi$  cannot be realized in band insulators where  $C_4T$  is exact. Surprisingly, using a real space construction (topological crystal), we find that an STI with  $\theta = \pi$  can arise in Anderson insulators with disorders respecting  $C_4T$  on average. To illustrate this state, we construct a lattice model and examine its phase diagram using the transfer matrix method up to the largest numerically accessible system size. An STI phase is identified through delocalized surface states and a half-quantized magneto-electric polarization in the bulk. As expected, an unavoidable gapless phase separates the STI from both clean insulators and trivial Anderson insulators, revealing the intrinsic nature of the STI. Moreover, we argue that the intrinsic STI is robust against electron-electron interactions, i.e., interactions cannot open an adiabatic path connecting the STI to a gapped clean system. Thus, our work provides the first intrinsic crystalline ASPT and its lattice realization. We also generalize the discussion to other crystalline symmetries.

*Introduction.* Topological insulators (TIs) [1–5], including topological crystalline insulators (TCIs) [6–10], are band insulators that are not adiabatically connected to atomic limits without breaking the protecting symmetry [11–14]. Their classification in clean systems has been well established in various schemes [15–26]. For TIs protected by local symmetries, disorder, as an inevitable effect in realistic materials, does not change the classifications, provided the disorder respects the protecting symmetries [16, 17, 27]. Surprisingly, Refs. [28–30] showed that for some TIs protected by local or crystalline symmetries, even when disorder breaks the protecting symmetries, the TIs can remain robust, as long as the disorder respects the symmetries on average. Such TIs were later conceptually clarified in Ref. [31] and were termed as statistical TIs (STIs). An STI is defined as an ensemble of disordered systems that manifest robust, delocalized boundary states, which are pinned at critical points by the average symmetries. A symmetry is said exact if every element in the ensemble respects it, and said average if the ensemble as a whole is invariant under the symmetry, though individual elements may break it. The disorder is always assumed short-range correlated, hence each element is self-averaging in the thermodynamic limit. As noted in Refs. [31, 32], all the known examples of STIs are adiabatically connected to clean TIs when the disorders are turned off, and the average symmetry becomes exact. We hence call them *extrinsic* STIs.

A closely related concept to STIs is the average symmetry-protected topological (ASPT) phase [33], which has recently gained attentions. ASPT phase is the many-body counterpart

of STI. An intriguing discovery is the *intrinsic* ASPT phase [34] that cannot be adiabatically connected to a clean symmetric system with a gap. Basing on this observation, we introduce and explore the concept of *intrinsic* STI referring to topological phases only realizable in strongly disordered insulators.

The 3D  $\mathbb{Z}_2$  TI protected by time-reversal symmetry (T) exhibits a topological magneto-electric effect described by the lagrangian term  $\mathcal{L}_\theta = \frac{\theta e^2}{4\pi^2\hbar} \mathbf{E} \cdot \mathbf{B}$  with  $\theta = \pi$  [35, 36]. If T is broken, other  $\theta$ -odd symmetries, such as inversion [9, 36–39], roto-reflections [40–43], translation followed by T [7, 44], and rotations  $(C_{n=2,3,4,6})$  followed by T [44–50], will also quantize  $\theta$  to 0 or  $\pi$ . It is therefore generally believed that these symmetries can protect TCIs with  $\theta = \pi$ , known as axion TIs. However, counterintuitively, we find that a  $C_4T$  symmetry, which satisfies  $(C_4T)^4 = 1$ , cannot protect a  $\theta = \pi$  state unless strong disorders leading to Anderson localization are introduced. (Note that such a  $C_4T$  can protect fragile topological band insulators [6, 44, 51], which have no stable surface state.) Our discovery marks the first example of intrinsic STI, highlighting a new type of topological phases.

*Extrinsic axion STI.* To begin, we first consider an extrinsic axion STI protected by an average inversion symmetry [52, 53]. If trivial local states are allowed to be added, clean TCIs can be adiabatically deformed to "topological crystals" [21, 22, 24], which consists of building blocks made up of lower-dimensional TIs, where the electron correlation length is much smaller than the lattice constant. The simplest topological crystal for an inversion-protected axion TI is illustrated in Fig. 1(a), where all the planes at integer (half-integer) z-coordinates are decorated with insulators with Chern number C=1 (-1). The cubic with unit length represents the unit cell. Each unit cell has eight inversion centers at  $x, y, z = 0, \frac{1}{2}$ .

<sup>\*</sup> These authors contribute equally to this work.

<sup>†</sup> songzd@pku.edu.cn

One can see that all the inversion centers in the system have been occupied by Chern insulators.

Now, we examine the spatial dependence of the local axion angle  $\theta$  in the topological crystal by analyzing the magnetoelectric response  $\mathcal{P}=\frac{\theta}{2\pi}\frac{e}{\Phi_0}\mathbf{B}$  [35, 36], where  $\Phi_0=h/e$  is the flux quantum. Suppose the 3D block above (below) the considered Chern insulator has an axion angle  $\theta_1$  ( $\theta_2$ ), and its volume is given by  $V_1=S\cdot L_1$  ( $V_2=S\cdot L_2$ ), where S represents the area of the Chern insulator. Then, under a perpendicular magnetic field of strength B, the electric charge accumulated on the Chern insulator is given by

$$\Delta Q = -\frac{\mathcal{P}_1 V_1}{L_1} + \frac{\mathcal{P}_2 V_2}{L_2} = \frac{\theta_2 - \theta_1}{2\pi} \frac{e}{\Phi_0} BS . \tag{1}$$

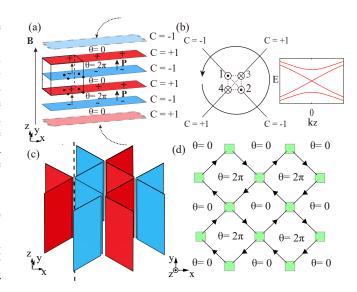
On the other hand, there must be  $\Delta Q=C\frac{e}{\Phi_0}BS$  according to the Streda formula of quantum Hall states [54], where C is the Chern number. The two expressions of  $\Delta Q$  together imply  $\theta_1-\theta_2=-2\pi C$ , meaning that a variation of  $\pm 2\pi$  in  $\theta$  corresponds to crossing a Chern insulator with  $C=\mp 1$ . Within each 3D block embedded between two Chern insulators,  $\theta$  must remain constant, as there is no electric response inside the region.

Since  $\theta=0$  in the vacuum, the value of  $\theta$  in each 3D block in Fig. 1(a) is uniquely determined to be either 0 or  $2\pi$ . Therefore, the average axion angle  $\bar{\theta}=\pi$ , provided that the distances between adjacent Chern insulators are equal, as required by the inversion symmetry. Note that a global change of  $-2\pi$  in  $\theta$  can be realized by introducing a Chern bubble at the boundary (by creating and adding the dashed planes in Fig. 1(a)), which does not affect the bulk physics. This indicates that  $\bar{\theta} \mod 2\pi$  is a  $\mathbb{Z}_2$  topological invariant.

We further demonstrate that  $\theta$  is always single-valued in insulating topological crystals, ensuring that the average  $\bar{\theta}$  is well-defined. In a general topological crystal, including the  $C_4T$ -symmetric state discussed below, a closed loop in space may cross multiple Chern insulators, as illustrated in Fig. 1(b). For the system to be insulating, the chiral edge modes of these Chern insulators must be locally gapped at the hinge where the Chern insulators intersect. This condition enforces that the net chirality (of chiral edge modes) enclosed by the loop to be zero, meaning that  $\theta$  undergoes an equal number of changes of  $\pm 2\pi$  around the loop. A  $2n\pi$  winding of  $\theta$  would correspond to n unpaired chiral modes enclosed by the loop, which should not appear in an insulating TCI.

Topological crystals for axion TIs are robust against weak quenched disorder respecting an average  $\theta$ -odd symmetry. First, intra-Chern-layer disorders do not alter the topology of individual Chern layers as long as they are below the critical value for the Quantum Hall transition, ensuring that  $\theta$  remains well-defined and single-valued. Second, inter-Chern-layer disorders may induce local fluctuations of  $\theta$  by effectively changing distances between layers with opposite Chern numbers. Nevertheless, the average  $\theta$ -odd symmetry still guarantees  $\bar{\theta} = \pi$ , as demonstrated in Ref. [52].

It has been shown that  $C_4T$ , as a  $\theta$ -odd symmetry, can protect a higher-order TI characterized by  $\bar{\theta}=\pi$  provided  $(C_4T)^4=-1$  [45, 50]. This state corresponds to the topological crystal shown in Fig. 1(c), (d), comprising four types



(a) The simplest topological crystal for an inversionprotected axion TI. The box shows a unit cell, and the black dots show inversion centers. Red (blue) planes show Chern insulators with C = 1(-1) with orientation +z.  $\theta$  is the local axion angle. (b) A closed loop in an insulating topological crystal must enclose chiral modes with zero net chirality, ensuring that  $\theta$  is single-valued. On a  $C_4T$ -symmetric hinge in (c), if  $(C_4T)^4 = 1$ , the  $(C_4T)^2 = -1$ subspace hosts Kramer helical states, while the  $(C_4T)^2 = 1$  subspace can be locally gapped, as shown by the 1D band structure on the right hand side. (c) A  $C_4T$ -symmetric topological crystal, where all  $C_4T$  axes are occupied by intersecting hinges of Chern layers. Red (blue) planes are Chern insulators with C = 1(-1) with normal  $(\mathbf{e}_x \pm \mathbf{e}_y)/\sqrt{2}$ . (d) shows the local axion angle of each 3D block embedded between Chern insulators in (c), viewed from the +z direction. The arrows show chiral modes on the z surface, separating 2D blocks with  $C = \pm 1/2$ .

of Chern layer blocks with normal vectors  $(\mathbf{e}_x + \mathbf{e}_y)/\sqrt{2}$ ,  $(\mathbf{e}_x - \mathbf{e}_y)/\sqrt{2}$ ,  $(-\mathbf{e}_x + \mathbf{e}_y)/\sqrt{2}$ ,  $(-\mathbf{e}_x - \mathbf{e}_y)/\sqrt{2}$  respectively, each with a Chern number of one along its normal. These blocks are connected via an array of  $C_4T$  axes, at each of which four Chern layers intersect and cyclically transform under  $C_4T$  symmetry. Each axis hosts two chiral edge modes propagating along  $\mathbf{e}_z$  and two anti-chiral edge modes propagating along  $-\mathbf{e}_z$  (Fig. 1(b)). Assuming sufficiently large Chern gaps, the bulk low-energy physics of the topological crystal arises from these edge modes. Since the net chirality is zero, one may expect a symmetric gap to be allowed at each axis. This expectation holds true if  $(C_4T)^4 = -1$ , as demonstrated in Refs. [55, 56], leading to a gapped topological crystal that realizes the clean axion TI.

Intrinsic axion STI. For  $(C_4T)^4=1$ , a symmetric gap is forbidden in the clean limit, ruling out the clean axion TI. Consider the four edge modes at a  $C_4T$  axis, labeled as 1, 2, 3, 4 (Fig. 1(b)). Without loss of generality, we assume 1, 2 and 3, 4 are chiral and anti-chiral, respectively.  $C_4T$  transforms these modes as  $1 \to 4 \to 2 \to 3 \to 1$ . Since  $(C_4T)^4=1$ , the 4D Hilbert space splits into two 2D subspaces with  $C_2=(C_4T)^2$  eigenvalues  $\pm 1$ . The  $C_2=-1$  subspace is spanned by  $\frac{1}{\sqrt{2}}(|1\rangle-|2\rangle)$  and  $\frac{1}{\sqrt{2}}(|3\rangle-|4\rangle)$ , which

have opposite chirality and form a Dirac point at  $k_z=0$ . Since  $(C_4T)^2=-1$  in this subspace, the Kramers' degeneracy protects the Dirac point from being gapped. In contrast, the  $C_2=1$  subspace, with  $(C_4T)^2=1$ , lacks Kramers' degeneracy and can be gapped. Thus, the absence of clean axion TI arises from Kramers' degeneracy in the  $C_2=-1$  subspace. In Ref. [56], following the topological crystal approach, we further show that  $C_4T$  satisfying  $(C_4T)^4=1$  does not protect any clean (stable) TI.

In addition to the topological crystal argument, we also mathematically proved  $\theta=0\pmod{2\pi}$  in  $C_4T$ -symmetric band insulators with  $(C_4T)^4=1$ . The magneto-electric polarization  $P_3=\theta/(2\pi)$  [3, 35] can be expressed through the winding number of the  $C_4T$  sewing matrix [41, 45, 50]

$$2P_3 = \int \frac{d^3 \mathbf{k}}{24\pi^2} \epsilon_{ijk} \operatorname{Tr}\left[ (B\partial_i B^{\dagger}) (B\partial_j B^{\dagger}) (B\partial_k B^{\dagger}) \right] \mod 2. \tag{2}$$

Here  $\partial_i \equiv \partial_{k_i}$ ,  $B_{mn}(\mathbf{k}) = \langle u_m \, (C_4 T \cdot \mathbf{k}) | \, C_4 T \, | \, u_n(\mathbf{k}) \rangle$  is the  $C_4 T$  sewing matrix, and  $|u_{m,n}(\mathbf{k})\rangle$  are Bloch states of occupied bands. Since the winding number of  $B(\mathbf{k})$  is an integer,  $P_3$  is quantized to 0 or 1/2 (mod 1), corresponding to trivial and axion insulators, respectively. We find that the winding number must be even if  $(C_4 T)^4 = 1$ , which enforces  $P_3 = 0$ . The proof is sketched here, with details in Ref. [56]. The occupied bands can be adiabatically deformed into disconnected one-band blocks (which contribute trivially to Eq. (2)) and two-band blocks. Each two-band block realizes a mapping from the Brillouin zone (T³) to SU(2), and its contribution to Eq. (2) is the degree of mapping, i.e., how many times it wraps SU(2). When  $(C_4 T)^4 = 1$ , there exists a reference point in SU(2) that the mapping must hit an even number of times, ensuring an even winding number.

To realize the *intrinsic* STI, we introduce Gaussian disorder with variance W at the hinges where Chern layers cross. This breaks the exact  $C_4T$  symmetry but preserves it on average. Since the bulk's low-energy physics is quasi-1D, a small W can localize the system without affecting the topology of the Chern layers, as disorder is confined to hinges. The local axion angle  $\theta$  of each 3D block between Chern layers can be determined as in Fig. 1(d), following the method we did for Fig. 1(a). The average  $\theta$  over 3D blocks is  $\pi$ . In the clean limit,  $\theta$  is ill-defined around metallic helical modes, but with disorder,  $\theta$  becomes well-defined and single-valued everywhere as the helical modes localize. Thus, the disor-

dered topological crystal behaves as an Anderson insulator with  $\bar{\theta} = \pi$ , protected by the average  $C_4T$  symmetry.

**Bulk-boundary correspondence.** The nontrivial topology of the disordered topological crystal also manifests itself as delocalized surface states. Specifically, consider the surface in the z direction. Chiral edge modes emerge at the boundaries of Chern layers, forming a network structure. As shown in Fig. 1(d), they resemble Chalker's model that describes the quantum Hall transition [57]. To draw an analogy with the quantum Hall transition, we assign effective Chern numbers (C's) to the 2D blocks on the surface. First, C's of two adjacent surface 2D blocks differ by  $\pm 1$ , as they are separated by a chiral mode. These blocks represent the surfaces of adjacent 3D bulk blocks with  $\theta = 0$ ,  $2\pi$ . Second, the  $C_4T$  symmetry, which exchanges the two types of blocks, imposes that their C's must be opposite. Thus, we assign effective Chern numbers  $C = \pm 1/2$  to the two types of surface 2D blocks. The chiral modes can then be interpreted as domain walls between regions with C = 1/2 and -1/2. In the clean limit, the chiral modes connect to the bulk helical modes at the  $C_4T$  axes represented by green squares. However, in the presence of disorders that localize bulk states, the green squares represent scattering nodes with random strengths and phase shifts. The average  $C_4T$  symmetry ensures that regions with C=1/2, -1/2 occupy equal areas. This symmetry condition pins the surface state at the critical point of the quantum Hall transition, where chiral modes percolate between  $C = \pm 1/2$  regions and remain delocalized.

A lattice model. Inspired by the topological crystal, we now construct a lattice model for the intrinsic STI. A pair of chiral modes on opposite edges of a Chern insulator can be regularized to a wire of lattice:  $2tk_z\sigma_z \rightarrow t\sin k_z\sigma_z + 2t(1-t)$  $\cos k_z)\sigma_x + m\sigma_x$ , where  $\sigma_z = \pm 1$  represents the chiral and anti-chiral modes around  $k_z = 0$ , and the mass term  $m\sigma_x$ mimics a coupling between the two edges. If the Chern layer reaches thermodynamic limit within one unit cell, there must be m=0. Here we use m as a tuning parameter. As will be shown below, a finite m drives the system away from the quasi-1D limit. Applying this regularization to the four Chern layers in the unit cell (Fig. 1(c)), we obtain an eight-band model shown in Fig. 2(a). Each pair of nearest neighbors in the xy plane form a wire that simulates a Chern layer. The red  $(\gamma)$  and dashed blue  $(\lambda)$  bonds represent couplings between the chiral and anti-chiral modes around the  $C_4T$  axes. The Hamiltonian is

$$H = \sum_{k_z,i} \zeta_i 2t \sin(k_z) c_{k_z,i}^{\dagger} c_{k_z,i} + \sum_{k_z,\langle i,j\rangle} (m + 2t(1 - \cos k_z)) c_{k_z,i}^{\dagger} c_{k_z,j} + \sum_{k_z,\langle \langle i,j\rangle\rangle} \gamma c_{k_z,i}^{\dagger} c_{k_z,j} + \sum_{k_z,\langle \langle i,j\rangle\rangle\rangle} \lambda c_{k_z,i}^{\dagger} c_{k_z,j}$$
(3)

where i, j label sites in xy plane,  $\zeta_i = 1, -1$  for white (chiral) and black (anti-chiral) sites respectively, and  $\langle \cdot \rangle, \langle \langle \cdot \rangle \rangle, \langle \langle \cdot \rangle \rangle$  represent first, second, and third nearest neighbor pairs, respectively. The model respects a  $C_4T$  symmetry satisfying

 $(C_4T)^4=1$ , which transforms the eight orbitals as  $1\to 3\to 4\to 2\to 1$ ,  $5\to 7\to 8\to 6\to 5$ . Even all the parameters are real, the time-reversal symmetry is inherently broken as chiral and anti-chiral modes from the same wire are coupled

to different  $C_4T$  centers. In Ref. [56] we find all the crystalline symmetries of this model, including a PT symmetry that squares to 1. In the following we focus on the state at half-filling. For m=0, the model's low energy physics consists of decoupled 1D helical modes, as we have explained in the topological crystal argument, and the entire  $k_z=0$  plane lies on the Fermi surface. For  $0<|m|<2\gamma$ , the model is a nodal line semi-metal protected by PT (Fig. 2(b)). For  $|m|>2\gamma$ , the system becomes a trivial band insulator.

Disorder is introduced by adding random imaginary components,  $\mathrm{i}\gamma'$ , to the hopping  $\gamma$  along the red bonds. The random variables  $\gamma'$  follows Gaussian distribution with a variant W.  $\gamma'$ s on different bonds are assumed uncorrelated. The  $C_4T$  symmetry is preserved on average because it maps one disorder configuration to another with equal probability, leaving the disorder ensemble invariant.

**Phase diagram.** The disordered lattice model is studied using the transfer matrix method in a quasi-1D geometry [57–59], where the longitudinal size M (along the x direction) is much larger than the transverse size  $L \times L$  (along the y and z directions). To study the localization of bulk states, we impose periodic boundary conditions along the y and z directions. The localization length  $\xi_{1D}(L)$  along the longitudinal direction, which depends on L, is obtained from the Lyapunov exponents of the transfer matrix. The normalized quasi-1D localization length  $\Lambda(L) = \xi_{1D}(L)/L$  characterizes the (de)localization behavior: etallic, critical, and localized states correspond to  $\lim_{L\to\infty}\Lambda(L)$  being divergent, finite, and vanishing, respectively.

On the insulating side of a metal-insulator phase transition, the 3D localization length  $\xi_{\rm 3D}$  diverges as  $|r-r_c|^{-\nu}$ , where r is the tuning parameter,  $r_c$  is the critical value, and  $\nu>0$  is a universal exponent.  $\Lambda(r,L)$  follows the one-parameter scaling law with the scaling variable  $L/\xi_{\rm 3D}$  for sufficiently large L [59]. For small L, an irrelevant correction to  $\Lambda$  due to the finite-size effect must be considered, and  $\Lambda$  takes the following form [60]:

$$\Lambda(r,L) = F(u_1(\tilde{r})L^{1/\nu}, u_2(\tilde{r})L^y) \tag{4}$$

where  $\tilde{r}=(r-r_c)/r_c,\ y<0$ , and  $F,u_1,u_2$  are undetermined functions that can be Taylor expanded near the phase transition point. The phase diagram in Fig. 2(d) is obtained by fitting Eq. (4) to numerically computed  $\Lambda$ . For example, in the insulator-metal transition shown in Fig. 2(c), we use W as the tuning parameter, and keep all other Hamiltonian parameters fixed. We obtain  $W_c=1.125$  [1.015, 1.162] and  $\nu=1.40$  [1.24, 1.56], which is consistent with previously reported value  $\nu=1.443$  [1.437, 1.449] for 3D Anderson transitions in the unitary class [61]. Other points on the phase boundary are determined similarly by choosing r=W or m. Further numerical details are provided in Ref. [56].

When m=0, the bulk's low energy states are quasi-1D and can be localized by arbitrarily small disorder strength W. This corresponds to a localization transition occurring at  $W_{c1}(0)=0$ . As will be discussed in the next paragraph, the resulting insulating phase is identified as the intrinsic STI. For sufficiently large W, the system evolves into a trivial Anderson insulator. This implies a delocalized phase transition

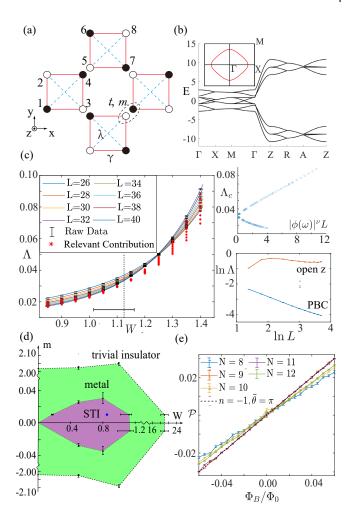


FIG. 2. (a) The lattice model viewed from the +z direction. Red (blue) lines represent  $\gamma$  ( $\lambda$ ). Black (white) circles represent chiral and anti-chiral modes. (b) Band structure of the lattice model with  $t=2, \gamma=1, \lambda=0.01$  and m=0.8. Inset shows the nodal line on the  $k_z = 0$  plane. (c) Numerical normalized quasi-1D localization length  $\Lambda$  with  $t=2, \gamma=1, \lambda=0.01, m=0.01$  and the Fermi energy  $E_F = -0.01$ . Left: Raw data and polynomial fitting of  $\Lambda$  near  $W_c \approx 1.125$ . Upper right: Collapse of the relevant contribution to  $\boldsymbol{\Lambda}$  to a one-parameter scaling function. Lower right: Comparison of  $\Lambda$  with W=0.85 between periodic boundary condition in y, z directions and open z boundary condition. (d) Phase diagram of the disordered lattice model with  $t=2, \gamma=1, \lambda=0.01$ and  $E_F = -0.01$ . The axion insulator phase (purple) is completely surrounded by a gapless phase (green), which is in turn surrounded by the trivial insulator phase (white). (e) The topological magnetoelectric response with m=0.01, W=0.85. Other parameters are the same as (d).

within the disorder range  $[W_{c2}(0),W_{c3}(0)]$  that separates the STI from the trivial Anderson insulator.  $W_{c2}(0)$  and  $W_{c3}(0)$  are esimated as 1.12 and 20.0, respectively. When m is small but nonzero, the bulk becomes a nodal-line semi-metal [62]. As W increases, the system undergoes a localization transition at a finite  $W_{c1}(m)$  [63–65], entering the STI phase. With further increase in W, the system experiences successive insulator-metal-insulator transitions at  $W_{c2}(m)$  and  $W_{c3}(m)$ ,

eventually reaching the trivial Anderson insulator phase. Notably,  $W_{c1}(m)$  and  $W_{c2}(m)$  merge at  $m\approx \pm 0.03$ , enclosing the intrinsic STI phase, which is separated from both the trivial Anderson insulator at  $W\to\infty$  and clean insulators at W=0.

Topological surface state. To demonstrate the delocalized surface state of the STI, we recalculate the normalized localization length  $\Lambda'(L)$  under an open boundary condition in the z-direction. This setup allows us to observe surface-specific phenomena, which are otherwise hidden under periodic boundary conditions. As discussed in Fig. 1(d), the surface state is expected to exhibit quantum Hall criticality. Using the parameters corresponding to the blue point within the STI phase in Fig. 2(d), we find that  $\Lambda'(L)$  indeed exhibits critical behavior - it remains constant as L approaches infinity. This behavior is in sharp contrast to the result under periodic boundary conditions, where  $\Lambda(L)$  decays with L and reveals localization, as shown in Fig. 2(c).

Topological magneto-electric effect. To further illustrate the nontrivial topology of the intrinsic STI, we directly compute the magneto-electric response of the disordered lattice model in a cubic geometry with  $N^3$  sites. Periodic boundary condition is imposed along the z direction to avoid delocalized surface states, while open boundary conditions are applied along x and y directions. A magnetic field B is introduced along the x direction, and the resulting electric polarization is measured as  $\mathcal{P} = \langle \hat{X} \rangle / N^3$ , where  $\langle \hat{X} \rangle$  is the expectation value of the x-coordinate for occupied states. Theoretically,  $\mathcal{P}$  is given by  $-(n+P_3)\Phi_B/\Phi_0$  where  $\Phi_B$  is the flux through a unit cell, n is a surface-dependent integer, and  $P_3 = \bar{\theta}/(2\pi)$ represents the magneto-electric polarization. The disorderaveraged  $\mathcal{P}$  (over 100 configurations) is plotted as a function of B in Fig. 2(e). The slope  $d\mathcal{P}/(d\Phi_B/\Phi_0)$  converges to  $\frac{1}{2}$ as N increases, confirming the topological magneto-electric effect characterized by  $P_3 = \frac{1}{2}$ .

**Discussions.** Based on topological crystal theory, winding number analysis in momentum space, numerical determination of localization length and topological magneto-electric effect, our work demonstrated the existence of intrinsic STI a new topological phase that has no band insulator correspondence. Furthermore, we argue that the STI is a well-defined intrinsic fermion ASPT even in the presence of electronelectron interactions. Within the topological crystal framework, an intrinsic ASPT is characterized by an obstruction to block decoration, where the system cannot be symmetrically gapped even with interactions, in the absence of disorder. However, the introduction of statistically symmetric disorder enables localization, leading to a short-range entangled bulk, while the boundary remains delocalized. In our case, the decorated Chern insulators around a  $C_4T$  axis generate onedimensional hinge modes exhibiting a U(1) and  $C_4T$  mixed anomaly, preventing a symmetric gap from forming even with interactions. By breaking  $C_4T$  symmetry down to an average symmetry through disorder, the anomaly constraint is lifted, allowing these modes to become localized and rendering the system's ground states short-range correlated. Indeed, the disordered 1D hinge problem maps to the boundary of a 2D topological insulator with average time-reversal symmetry, where boundary states are known to localize in the presence of interactions [66]. Thus, the topological crystal construction still realizes the same intrinsic STI even with interactions present.

In Ref. [56], we also generalize the discussions to a  $C_2T$  symmetry squaring to -1.

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# Appendix

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# A. Absence of clean axion insulator $((C_4T)^4 = 1)$ : Momentum space proof

In this section, we prove that a  $C_4T$ -symmetric band insulator must have a vanishing magneto-electric polarization  $P_3$  if  $(C_4T)^4=1$ .

#### 1. $P_3$ and the winding number of sewing matrix

In a band insulator, the magneto-electric polarization  $P_3 = \frac{\theta}{2\pi}$  can be calculated as a Chern-Simons integral [3, 35]

$$P_3 = \frac{1}{16\pi^2} \int d^3 \mathbf{k} \, \epsilon_{ijk} \text{Tr} \left[ \left( \mathcal{F}^{ij}(\mathbf{k}) - \frac{2}{3} i \mathcal{A}^i(\mathbf{k}) \mathcal{A}^j(\mathbf{k}) \right) \mathcal{A}^k(\mathbf{k}) \right] \quad \text{mod } 1.$$
 (A1)

where the indices i, j, k = x, y, z are implicitly summed when repeated,  $\epsilon_{ijk}$  is the Levi-Civita symbol. The non-Abelian Berry connection and curvature are defined as

$$\mathcal{A}_{mn}^{i}(\mathbf{k}) = -i\langle u_{m}(\mathbf{k})|\partial_{i}|u_{n}(\mathbf{k})\rangle, \qquad \mathcal{F}^{ij} = \partial_{i}\mathcal{A}^{j} - \partial_{j}\mathcal{A}^{i} + i[\mathcal{A}^{i}, \mathcal{A}^{j}], \qquad (A2)$$

respectively, where  $\partial_i \equiv \partial_{k_i}$ . One should not confuse the minus sign in  $\mathcal{A}^i$ . The band indices m, n are limited to the occupied bands. Upon a gauge transformation within occupied bands  $|u_n(\mathbf{k})\rangle \to |u_l(\mathbf{k})\rangle U_{nl}^*(\mathbf{k})$ , where repeated band indices are implicitly summed, the Berry connection and curvature transform as

$$\mathcal{A}^i \to U \mathcal{A}^i U^\dagger - i U \partial_i U^\dagger, \qquad \mathcal{F}^{ij} \to U \mathcal{F}^{ij} U^\dagger,$$
 (A3)

respectively. Substituting the gauge transformation into Eq. (A1), we obtain the change of the integral

$$\Delta P_{3} = \frac{1}{16\pi^{2}} \int d^{3}\mathbf{k} \, \epsilon_{ijk} \operatorname{Tr} \left[ \frac{2}{3} \left( U^{\dagger} \partial_{i} U \right) \left( U^{\dagger} \partial_{j} U \right) \left( U^{\dagger} \partial_{k} U \right) + i \mathcal{F}^{ij} (U^{\dagger} \partial_{k} U) + \frac{2}{3} \mathcal{A}^{i} \mathcal{A}^{j} (U^{\dagger} \partial_{k} U) + \frac{2}{3} (U^{\dagger} \partial_{i} U) \mathcal{A}^{j} \mathcal{A}^{k} \right]$$

$$+ \frac{2}{3} \mathcal{A}^{i} (U^{\dagger} \partial_{j} U) \mathcal{A}^{k} + \frac{2i}{3} (U^{\dagger} \partial_{i} U) (U^{\dagger} \partial_{j} U) \mathcal{A}^{k} + \frac{2i}{3} \mathcal{A}^{i} (U^{\dagger} \partial_{j} U) (U^{\dagger} \partial_{k} U) + \frac{2i}{3} (U^{\dagger} \partial_{i} U) \mathcal{A}^{j} (U^{\dagger} \partial_{k} U) \right]. \tag{A4}$$

Using the cyclic condition of trace, we simplify it to

$$\Delta P_{3} = \frac{1}{16\pi^{2}} \int d^{3}\mathbf{k} \, \epsilon_{ijk} \operatorname{Tr} \left[ \frac{2}{3} \left( U^{\dagger} \partial_{i} U \right) \left( U^{\dagger} \partial_{j} U \right) \left( U^{\dagger} \partial_{k} U \right) + i \mathcal{F}^{ij} \left( U^{\dagger} \partial_{k} U \right) + 2 \mathcal{A}^{i} \mathcal{A}^{j} \left( U^{\dagger} \partial_{k} U \right) - 2i \mathcal{A}^{j} \left( \partial_{k} U^{\dagger} \right) (\partial_{i} U) \right] \right]. \tag{A5}$$

Expanding  $\mathcal{F}^{ij}$  in terms of the Berry connection, we find that the last three terms in the above equation sum to a full derivative term

$$\frac{1}{16\pi^2} \int d^3 \mathbf{k} \, \epsilon_{ijk} \text{Tr} \left[ 2\mathrm{i}(\partial_i \mathcal{A}^j) (U^{\dagger} \partial_k U) - 2\mathcal{A}^i \mathcal{A}^j (U^{\dagger} \partial_k U) + 2\mathcal{A}^i \mathcal{A}^j (U^{\dagger} \partial_k U) + 2\mathrm{i}\mathcal{A}^j (\partial_i U^{\dagger}) (\partial_k U) \right] 
= \frac{1}{16\pi^2} \int d^3 \mathbf{k} \, \epsilon_{ijk} \cdot \partial_i \cdot \text{Tr} \left[ 2\mathrm{i} \, \mathcal{A}^j (U^{\dagger} \partial_k U) \right] = 0 \,.$$
(A6)

Then

$$\Delta P_3 = \frac{1}{24\pi^2} \int d^3 \mathbf{k} \, \epsilon_{ijk} \text{Tr}[\left(U^{\dagger} \partial_i U\right) \left(U^{\dagger} \partial_j U\right) \left(U^{\dagger} \partial_k U\right)] \tag{A7}$$

has the form of a 3D winding number, which is an integer. Therefore,  $P_3$  defined in Eq. (A1) is a gauge invariant quantity after modulo 1.

Now let us see how  $P_3$  is quantized by a  $C_4T$  symmetry. We do not specify  $(C_4T)^4 = 1$  or -1 in this subsection.

The following derivation parallels that in Refs. [35, 41]. We define the  $C_4T$  sewing matrix as

$$B_{mn}(\mathbf{k}) = \langle u_m(C_4 T \cdot \mathbf{k}) | C_4 T | u_n(\mathbf{k}) \rangle, \tag{A8}$$

where  $C_4T \cdot \mathbf{k} = (k_y, -k_x, -k_z)$ . It is direct to verify that  $B_{mn}(\mathbf{k})$  is unitary and periodic over the Brillouin zone. It immediately follows

$$C_4 T |u_n(\mathbf{k})\rangle = |u_m(C_4 T \cdot \mathbf{k})\rangle \cdot B_{mn}(\mathbf{k}), \qquad |u_m(C_4 T \cdot \mathbf{k})\rangle = B_{mn}^*(\mathbf{k}) \cdot C_4 T \cdot |u_n(\mathbf{k})\rangle, \tag{A9}$$

where implicit summations over repeated band indices are limited to occupied bands. We write  $C_4T \cdot \mathbf{k}$  as  $\mathbf{k}'$  for simplicity. The coordinate transformation has the form  $k_i' = R_{ij}k_j$ , with  $R \cdot R^T = 1$ ,  $\det R = -1$ . The derivatives with respect to k ( $\partial$ ) and k' ( $\partial'$ ) are related by  $\partial_i = R_{ji}\partial_j'$ ,  $\partial_i' = R_{ij}\partial_j$ . The non-Abelian Berry connection defined in the new coordinate is

$$\widetilde{\mathcal{A}}_{mn}^{i}(\mathbf{k}') \equiv -i\langle u_{m}(\mathbf{k}')|\partial_{i}'|u_{n}(\mathbf{k}')\rangle = -i\langle u_{m}(\mathbf{k}')|R_{ij}\partial_{j}|u_{n}(\mathbf{k}')\rangle = -iR_{ij}B_{mm'}(\mathbf{k})\langle C_{4}T \cdot u_{m'}(\mathbf{k})|\partial_{j}\left[|C_{4}T \cdot u_{n'}(\mathbf{k})\rangle B_{nn'}^{*}(\mathbf{k})\right] 
= -iR_{ij}B_{mm'}(\mathbf{k})\langle u_{m'}^{*}(\mathbf{k})|\partial_{j}|u_{n'}^{*}(\mathbf{k})\rangle B_{nn'}^{*}(\mathbf{k}) - iR_{ij}B_{ml}(\mathbf{k})\partial_{j}B_{nl}^{*}(\mathbf{k}) 
= -R_{ij}[B(\mathbf{k})\mathcal{A}^{j*}(\mathbf{k})B^{\dagger}(\mathbf{k})]_{mn} - iR_{ij}[B(\mathbf{k})\partial_{j}B^{\dagger}(\mathbf{k})]_{mn}.$$
(A10)

After a few steps of algebra, one can also derive

$$\widetilde{\mathcal{F}}^{ij}(\mathbf{k}') \equiv \partial_i' \widetilde{\mathcal{A}}^j(\mathbf{k}') - \partial_i' \widetilde{\mathcal{A}}^i(\mathbf{k}') + \mathrm{i} [\widetilde{\mathcal{A}}^i(\mathbf{k}'), \widetilde{\mathcal{A}}^j(\mathbf{k}')] = -R_{ii'} R_{jj'} B(\mathbf{k}) \mathcal{F}^{i'j'*}(\mathbf{k}) B^{\dagger}(\mathbf{k}) . \tag{A11}$$

Suppose

$$q + P_3 = \frac{1}{16\pi^2} \int d^3 \mathbf{k} \, \epsilon_{ijk} \text{Tr} \left[ \left( \mathcal{F}^{ij}(\mathbf{k}) - \frac{2}{3} i \mathcal{A}^i(\mathbf{k}) \mathcal{A}^j(\mathbf{k}) \right) \mathcal{A}^k(\mathbf{k}) \right]$$

$$= \frac{1}{16\pi^2} \int d^3 \mathbf{k}' \epsilon_{ijk} \text{Tr} \left[ \left( \widetilde{\mathcal{F}}^{ij}(\mathbf{k}') - \frac{2}{3} i \widetilde{\mathcal{A}}^i(\mathbf{k}') \widetilde{\mathcal{A}}^j(\mathbf{k}') \right) \widetilde{\mathcal{A}}^k(\mathbf{k}') \right] . \tag{A12}$$

The two rows are the same quantity expressed in two coordinate systems, hence they equal to each other. Here q is the gauge-dependent integer part of the integral, and  $P_3$  ranges from 0 to 1. Inserting Eqs. (A10) and (A11) to the second expression, we obtain

$$q + P_3 = \frac{1}{16\pi^2} \int d^3 \mathbf{k} \epsilon_{ijk} R_{ii'} R_{jj'} R_{kk'} \text{Tr} \left[ \left( B \mathcal{F}^{i'j'*} B^{\dagger} + \frac{2i}{3} (B \mathcal{A}^{i'*} B^{\dagger} + iB \partial_{i'} B^{\dagger}) (B \mathcal{A}^{j'*} B^{\dagger} + iB \partial_{j'} B^{\dagger}) \right) (B \mathcal{A}^{k'*} B^{\dagger} + iB \partial_{k'} B^{\dagger}) \right]. \tag{A13}$$

Since  $\epsilon_{ijk}R_{ii'}R_{jj'}R_{kk'} = \det R \cdot \epsilon_{i'j'k'}$  and  $\det R = -1$ , the above equation becomes

$$q + P_{3} = -\frac{1}{16\pi^{2}} \int d^{3}\mathbf{k} \, \epsilon_{ijk} \text{Tr} \left[ \left( B \mathcal{F}^{ij*} B^{\dagger} + \frac{2i}{3} (B \mathcal{A}^{i*} B^{\dagger} + iB \partial_{i} B^{\dagger}) (B \mathcal{A}^{j*} B^{\dagger} + iB \partial_{j} B^{\dagger}) \right) (B \mathcal{A}^{k*} B^{\dagger} + iB \partial_{k} B^{\dagger}) \right]$$

$$= -\frac{1}{16\pi^{2}} \int d^{3}\mathbf{k} \, \epsilon_{ijk} \text{Tr} \left[ \left( \mathcal{F}^{ij}(\mathbf{k}) - \frac{2}{3} i \mathcal{A}^{i}(\mathbf{k}) \mathcal{A}^{j}(\mathbf{k}) \right) \mathcal{A}^{k}(\mathbf{k}) \right]^{*} - \frac{1}{24\pi^{2}} \int d^{3}\mathbf{k} \, \epsilon_{ijk} \text{Tr} \left[ (B \partial_{i} B^{\dagger}) (B \partial_{j} B^{\dagger}) (B \partial_{k} B^{\dagger}) \right]$$

$$-\frac{1}{16\pi^{2}} \int d^{3}\mathbf{k} \, \epsilon_{ijk} \text{Tr} \left[ -i \mathcal{F}^{ij*} (B^{\dagger} \partial_{k} B) + \frac{2}{3} \mathcal{A}^{i*} \mathcal{A}^{j*} (B^{\dagger} \partial_{k} B) + \frac{2}{3} \mathcal{A}^{i*} (B^{\dagger} \partial_{j} B) \mathcal{A}^{k*} + \frac{2}{3} (B^{\dagger} \partial_{i} B) \mathcal{A}^{j*} \mathcal{A}^{k*}$$

$$-\frac{2i}{3} (B^{\dagger} \partial_{i} B) (B^{\dagger} \partial_{j} B) \mathcal{A}^{k*} - \frac{2i}{3} (B^{\dagger} \partial_{i} B) \mathcal{A}^{j*} (B^{\dagger} \partial_{k} B) - \frac{2i}{3} \mathcal{A}^{i*} (B^{\dagger} \partial_{j} B) (B^{\dagger} \partial_{k} B) \right]. \tag{A14}$$

The first term in the second row equals to  $-q - P_3$ . The complex conjugations of the last seven terms (in the third and fourth rows) share the same form as the last seven terms in Eq. (A4), which have been shown as a full derivative term. Then, there must be

$$2P_3 = -\frac{1}{24\pi^2} \int d^3 \mathbf{k} \, \epsilon_{ijk} \text{Tr} \left[ (B\partial_i B^{\dagger}) (B\partial_j B^{\dagger}) (B\partial_k B^{\dagger}) \right] \quad \text{mod } 2.$$
 (A15)

Since the integral on the right hand side is a 3D winding number (an integer),  $P_3$  is either 0 or  $\frac{1}{2}$  mod 1. Therefore, in the presence of a  $C_4T$  symmetry, regardless of  $(C_4T)^4=1$  or -1,  $P_3$  can only take value 0 or  $\frac{1}{2}$ .

We have assumed a smooth  $B(\mathbf{k})$  to validate the differentials in Eq. (A15). This can be fulfilled when the system does not exhibit 3D Chern numbers: For topological states protected by symmetries (translation excluded), one can always choose a symmetry-breaking Wannier gauge [11] where the states are smooth over the Brillouin zone.

#### 2. Trivial $P_3$

In this subsection we prove  $P_3=0$  if  $(C_4T)^4=1$  by showing that the winding number on the right hand side of Eq. (A15) is always even. First, we block-diagonalize the  $C_4T$  sewing matrix B into two-by-two and one-by-one blocks. A one-by-one block always contributes zero to the winding number. Each two-by-two block  $B^r$   $(r=1,2\cdots)$  realizes a mapping from the 3D torus  $T^3$  to  $SU(2) \sim S^3$  and contributes a factor  $deg[B^r]$  - degree of the mapping- to the winding number [36, 50].  $deg[B^r]$  counts how many times the domain manifold  $(T^3)$  wraps around the target manifold SU(2). One can choose a regular value

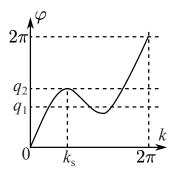


FIG. 3. A Map f from  $S^1$  to  $S^1$ . To calculate the parity of  $\deg[f]$ , one can choose a regular value, e.g.,  $q_1$ , in the target manifold and count its preimages. The parity of the number of preimages gives  $\deg[f]$  mod 2. One should not use a critical value, e.g.,  $q_2$ , for the counting.

 $q_{\text{ref}} \in \text{SU}(2)$  and counts how many times  $q_{\text{ref}}$  is hit by the mapping  $B^r$ , as illustrated in Fig. 3. Parity of the counting gives  $\deg[B^r] \mod 2$ , and hence determines  $P_3$ . We will prove that, if  $(C_4T)^4 = 1$ , there exists such a  $q_{\text{ref}}$  that the counting is always even, implying  $P_3 = 0$ .

We introduce the sewing matrix for  $C_2 = (C_4 T)^2$ 

$$D_{mn}(\mathbf{k}) = \langle u_m(C_2\mathbf{k})|C_2|u_n(\mathbf{k})\rangle. \tag{A16}$$

 $D(\mathbf{k})$  is unitary and periodic over the Brillouin zone. It is related to the  $C_4T$  sewing matrix via

$$D_{mn}(\mathbf{k}) = \langle u_m(C_2\mathbf{k})|C_4T \cdot C_4T|u_n(\mathbf{k})\rangle = \langle u_m(C_2\mathbf{k})|C_4T \Big[|u_l(C_4T \cdot \mathbf{k})B_{ln}(\mathbf{k})\Big] = [B(C_4T \cdot \mathbf{k})B^*(\mathbf{k})]_{mn}, \quad (A17)$$

where Eq. (A9) is inserted. Thus, the  $C_4T$  sewing matrix at  $C_4T \cdot \mathbf{k}$  is related to that at  $\mathbf{k}$  by

$$B(C_4T \cdot \mathbf{k}) = D(\mathbf{k}) \cdot B^T(\mathbf{k}). \tag{A18}$$

Applying this equation twice, we obtain

$$B(C_2 \cdot \mathbf{k}) = D(C_4 T \cdot \mathbf{k}) \cdot B^T(C_4 T \cdot \mathbf{k}) = D(C_4 T \cdot \mathbf{k}) \cdot B(\mathbf{k}) \cdot D^T(\mathbf{k}). \tag{A19}$$

For later convenience, we define the high symmetry momenta

$$\Gamma: (0,0,0), \qquad X: (\pi,0,0), \qquad Y: (0,\pi,0), \qquad M: (\pi,\pi,0)$$
  
 $Z: (0,0,\pi), \qquad R: (\pi,0,\pi), \qquad T: (0,\pi,\pi), \qquad A: (\pi,\pi,\pi).$ 

There are four  $C_2$ -invariant high symmetry lines:  $\Gamma Z$ , XR, YT, MA. For  $\mathbf{k}$  belonging to these lines,  $D(\mathbf{k})$  is a diagonal matrix consisting of  $C_2$  eigenvalues. Since  $C_2^2=1$ , the  $C_2$  eigenvalues can only be  $\pm 1$ . There are four  $C_4T$ -invariant high symmetry momenta  $K^4=\{\Gamma,M,Z,A\}$ . For  $\mathbf{k}_0\in K^4$ , the sewing matrix B must satisfy  $B(\mathbf{k}_0)=D(\mathbf{k}_0)B^T(\mathbf{k}_0)$ . A  $D(\mathbf{k}_0)=-1$  eigenvalue must be at least doubly degenerate because the minimal  $B(\mathbf{k}_0)$  matrix satisfying  $B(\mathbf{k}_0)=-B^T(\mathbf{k}_0)$  is  $e^{i\alpha}\sigma_y$ , where  $\alpha$  is an arbitrary phase factor. States at X or Y are generally non-degenerate, and there must be  $D(X)=D^*(Y)$  according to Eq. (A19).

For simplicity, we assume there is no accidental degeneracy within the occupied bands. If an accidental degeneracy happens, we add a symmetry-allowed perturbation term to lift it. This operation does not change the value of  $P_3$  of the occupied bands. (To be concrete, let us consider Weyl points between two nearby bands. According to the  $C_4T$  symmetry, the irreducible Brillouin zone is  $\frac{1}{4}$  of the full Brillouin zone. Since the  $C_4T$  symmetry preserves the topological charges of Weyl points, the irreducible Brillouin zone and its  $C_4T$  partners must have the same charge. Thus, according to the Nielsen-Ninomiya theorem [67, 68], which guarantees a vanishing total topological charge in lattice models, the irreducible Brillouin zone must also have a zero topological charge. The irreducible Brillouin zone could have pairs of Weyl points with opposite charges, but one can design proper continuous deformation to annihilate them within the irreducible Brillouin zone.) The only remained degeneracies are the  $D(\mathbf{k}_0) = -1$  states at  $\mathbf{k}_0 \in K^4$ . Then the occupied bands decompose into a set of disconnected groups, as shown in Fig. 4(a) and (b). The sewing matrices then have block-diagonal forms:

$$D(\mathbf{k}) = \bigoplus_{r} D^{r}(\mathbf{k}), \qquad B(\mathbf{k}) = \bigoplus_{r} B^{r}(\mathbf{k}).$$
 (A20)

A 1D block must have  $D^r(\Gamma, M) = 1$  such that no Kramer degeneracy appears. We then identify two types of 1D blocks in terms of  $C_2$  eigenvalues

$$D^{r}(\Gamma) = 1, \qquad D^{r}(M) = 1, \qquad D^{r}(X) = \pm 1.$$
 (A21)

Similarly, there are nine types of 2D blocks in terms of  $C_2$  eigenvalues:

$$D^r(\Gamma) = -\sigma_0, \qquad D^r(M) = -\sigma_0, \qquad D^r(X) = \sigma_0, -\sigma_0, \sigma_z,$$
 (A22)

$$D^r(\Gamma) = -\sigma_0, \qquad D^r(M) = \sigma_0, \qquad D^r(X) = \sigma_0, -\sigma_0, \frac{\sigma_z}{\sigma_z},$$
 (A23)

$$D^r(\Gamma) = \sigma_0, \qquad D^r(M) = -\sigma_0, \qquad D^r(X) = \sigma_0, -\sigma_0, \frac{\sigma_z}{\sigma_0}.$$
 (A24)

There is no higher dimensional block. The blocks contribute to the winding number in Eq. (A15) independently. Since the  $C_2$  symmetry does not protect any stable band topology [55, 69], and we are not considering 3D Chern insulators in this work, the  $C_2$  sewing matrix  $D(\mathbf{k})$  should take form of band representations (BRs) [12] - symmetry-allowed atomic limits - of the space group P2, or represent fragile topological states of P2. We will discuss the complexity from  $C_2$  sewing matrix in Sec. A 3 and for now only focus on the simplest  $\mathbf{k}$ -independent choices

$$D^r(\mathbf{k}) = 1, \qquad D^r(\mathbf{k}) = -\sigma_0 \tag{A25}$$

for 1D and 2D blocks, respectively. Since no block exhibits 3D Chern numbers,  $B^r(\mathbf{k})$  can be smoothly defined over the Brillouin zone. We do *not* assume a diagonal structure of  $B^r(\mathbf{k})$  on the energy eigenstates, which may lead to some singularities in  $B^r(\mathbf{k})$ .

We consider a U(1) gauge transformation to the r-th block:  $|u_n'(\mathbf{k})\rangle = |u_n(\mathbf{k})\rangle e^{\mathrm{i}\varphi(\mathbf{k})/d_r}$ , where  $\varphi(\mathbf{k})$  is smoothly defined over the Brillouin zone and  $d_r=1$  or 2 is the dimension of the r-th block.  $\varphi(\mathbf{k})$  should exhibit even (if nonzero) winding numbers across the Brillouin zone for  $d_r=2$  to ensure the periodicity of  $|u_n'(\mathbf{k})\rangle$ . The  $C_4T$  and  $C_2$  sewing matrices on the transformed basis are

$$B^{r'}(\mathbf{k}) = e^{-\frac{i}{d_r}(\varphi(C_4T \cdot \mathbf{k}) + \varphi(\mathbf{k}))} B^r(\mathbf{k}), \qquad D^{r'}(\mathbf{k}) = e^{-\frac{i}{d_r}(\varphi(C_2 \cdot \mathbf{k}) - \varphi(\mathbf{k}))} D^r(\mathbf{k}), \tag{A26}$$

respectively. The purpose of this gauge transformation will become clear in the next paragraph. We require  $\varphi(C_2 \cdot \mathbf{k}) = \varphi(\mathbf{k})$  such that the constant D sewing matrices in Eq. (A25) remain unchanged under the transformation. If  $\varphi$  can be chosen to satisfy

$$i(\varphi(C_4T\mathbf{k}) + \varphi(\mathbf{k})) = \ln \det B^r(\mathbf{k}), \qquad \varphi(C_2 \cdot \mathbf{k}) = \varphi(\mathbf{k}),$$
 (A27)

then  $\det B^{r'}(\mathbf{k}) = 1$  and  $D^{r'}(\mathbf{k}) = D^{r}(\mathbf{k})$  (Eq. (A25)) are fulfilled in the same gauge. We now examine whether there are topological obstructions to Eq. (A27):

- (i) Denote  $\vartheta(\mathbf{k}) = \varphi(C_4T\mathbf{k}) + \varphi(\mathbf{k})$ . As  $\varphi$  is smoothly defined over the Brillouin zone,  $\vartheta(\mathbf{k})$  must have vanishing winding numbers on arbitrary contractable loops.  $\ln \det B^r(\mathbf{k})$  must also have vanishing winding numbers on contractable loops as  $B^r(\mathbf{k})$  is smoothly defined over the Brillouin zone (see discussions below Eq. (A15)).
- (ii)  $\vartheta(\mathbf{k})$  must have vanishing winding number on the non-contractable loop  $\mathcal{C}_z:(0,0,-\pi)\to(0,0,\pi)$  because  $\vartheta(0,0,k_z)=\vartheta(0,0,-k_z)$  by definition. For the considered  $C_2$  sewing matrices in Eq. (A25), Eq. (A18) implies  $\det B^r(0,0,k_z)=\det B^r(0,0,-k_z)$ , meaning  $\det B^r(\mathbf{k})$  also has vanishing winding number along  $\mathcal{C}_z$ .
- (iii) The winding numbers of  $\vartheta(\mathbf{k})$  along non-contractable loops  $\mathcal{C}_x: (-\pi,0,0) \to (\pi,0,0), \mathcal{C}_y: (0,-\pi,0) \to (0,\pi,0)$  must be zero because  $\vartheta(\mathbf{k}) = \vartheta(C_2 \cdot \mathbf{k})$  by definition. For the considered sewing matrices in Eq. (A25), Eq. (A18) also implies vanishing winding numbers of  $\ln \det B^r(\mathbf{k})$  along  $\mathcal{C}_{x,y}$ .

Since there is no topological obstruction to Eq. (A27), one can find such a gauge where  $\det B^{r\prime}(\mathbf{k})=1$  and  $D^{r\prime}(\mathbf{k})$  is given by Eq. (A25). Moreover, as  $\vartheta(\mathbf{k})$  has vanishing winding numbers along non-contractable loops,  $B^{r\prime}(\mathbf{k})$  (Eq. (A26)) remains periodic over the Brillouin zone [36]. In the following we will stick to this gauge and relabel  $B^{r\prime}(\mathbf{k})$ ,  $D^{r\prime}(\mathbf{k})$  as  $B^{r}(\mathbf{k})$ ,  $D^{r}(\mathbf{k})$ , respectively.

A 1D block always has  $B^r(\mathbf{k}) = 1$  and hence contributes trivially to the winding number. For a 2D block,  $B^r$  realizes a mapping from BZ  $\sim$  T<sup>3</sup> to SU(2)  $\sim$  S<sup>3</sup>. Then, the right hand side of Eq. (A15) reduces to [36, 50]

$$\sum_{r} \deg[B^r] \mod 2 \tag{A28}$$

with  $deg[B^r]$  being the degree of the mapping between oriented manifolds with the same dimension [70]. The degree can be computed via a simple counting

$$\deg[B^r] = \sum_{\mathbf{k} \in (B^{r-1})[q_{\text{ref}}]} \operatorname{sgn}_{\mathbf{k}}[B^r] . \tag{A29}$$

Here  $q_{\rm ref} \in {\rm SU}(2)$  is a *regular value* of the mapping, meaning that at each preimage  ${\bf k} \in (B^{r-1})[q_{\rm ref}]$ , the mapping has a full-rank Jacobian. ( ${\bf k}$  is a regular (critical) point if the local Jacobian is (not) full-rank, and its image is a regular (critical) value.) See Fig. 3 for example.  ${\rm sgn}_{\bf k}[B^r]$  is the sign of the Jacobian determinant, which equals to +1 (-1) if the local mapping around  ${\bf k}$  keeps (reverses) the orientation of the manifold. We need to choose a convenient reference point  $q_{\rm ref}$  to evaluate Eq. (A28). We notice that Eq. (A18) and  $D^r({\bf k}) = -\sigma_0$  imply

$$\forall \mathbf{k}_0 \in K^4, \qquad B^r(\mathbf{k}_0) = -B^{rT}(\mathbf{k}_0) \qquad \Rightarrow \qquad B^r(\mathbf{k}_0) = \pm i\sigma_y \ . \tag{A30}$$

Let us first try the reference point  $q_{\rm ref}={\rm i}\sigma_y$ . If there is  $B^r({\bf k})={\rm i}\sigma_y$  for some  ${\bf k}\not\in K^4$ , then there must be  $B^r(C_4T\cdot{\bf k})=-B^{rT}({\bf k})={\rm i}\sigma_y$ . We can reasonably assume that such  ${\bf k}\not\in K^4$  are regular points where the Jacobian is full-rank: Even if  ${\bf k}$  was critical, the singularity is not enforced by symmetry and hence can be removed. In particular, a  $C_2$ -symmetric momentum  ${\bf k}_1$  must be critical. This follows from Eq. (A19) and  $D^r({\bf k}_1)=-\sigma_0$ , which together imply that  $B^r({\bf k}_1+{\bf p})$  must be even in  $p_x,p_y$ , leading to a vanishing Jacobian determinant at  ${\bf k}_1$ . While  $B^r({\bf k}_1)={\rm i}\sigma_y$  could occur accidentally at a  $C_2$ -symmetric  ${\bf k}_1\not\in K^4$ , we can avoid this by adding perturbation to the Hamiltonian or applying a gauge transformation to  $B^r({\bf k})$ , moving the preimage of  ${\rm i}\sigma_y$  to one or more regular points in the neighborhood of  ${\bf k}_1$ . Since this happens at  ${\bf k}_1$  and  $C_4T\cdot {\bf k}_1$  simultaneously, the contribution to  ${\rm deg}[B^r]$  (Eq. (A29)) is always even. Thus, we only need to examine contributions from  $K^4$ . A  ${\bf k}_0\in K^4$  is a untomatically  $C_2$ -symmetric and hence critical. However, unlike other  $C_2$ -symmetric points, if  ${\bf k}_0\in K^4$  is a preimage of  ${\bf i}\sigma_y$ , one cannot continuously move the preimage to its neighborhood by a perturbation to the Hamiltonian or a gauge transformation because  $B^r({\bf k}_0)$  can only take discrete values  $\pm {\bf i}\sigma_y$  due to Eq. (A30). Nevertheless, we can perturbatively change the reference point  $q_{\rm ref}$  such that  ${\bf k}_0$  is no longer a preimage of the new  $q_{\rm ref}$ . In the next two paragraphs we will show that  ${\bf k}_0$  will split into an even number of regular preimages upon the change of  $q_{\rm ref}$ , hence each  ${\bf k}_0$  also contributes trivially to  ${\rm deg}[B^r]$  mod 2. Thus,  ${\rm deg}[B^r]$  mod 2 is always zero.

We parameterize  $B^r(\mathbf{k})$  around a preimage  $\mathbf{k}_0 \in K^4$  of  $i\sigma_y$ . Consider  $\mathbf{k} = \mathbf{k}_0 + \mathbf{p}$  with  $\mathbf{p}$  being a small quantity, Eq. (A18) and  $D^r(\mathbf{k}) = -\sigma_0$  imply

$$B^{r}(\mathbf{k}_{0} + \mathbf{p}) = \sum_{\mu=0,x,y,z} d_{\mu}(\mathbf{p})\sigma_{\mu} = [\beta_{01}p_{z} + \beta_{02}(p_{x}^{2} - p_{y}^{2}) + 2\beta_{03}p_{x}p_{y}]\sigma_{0} + [\beta_{11}p_{z} + \beta_{12}(p_{x}^{2} - p_{y}^{2}) + 2\beta_{13}p_{x}p_{y}]i\sigma_{x} + [1 + \alpha_{21}p_{z}^{2} + \alpha_{22}(p_{x}^{2} + p_{y}^{2})]i\sigma_{y} + [\beta_{31}p_{z} + \beta_{32}(p_{x}^{2} - p_{y}^{2}) + 2\beta_{33}p_{x}p_{y}]i\sigma_{z} + \mathcal{O}(p^{3}),$$
(A31)

where  $\alpha$ ,  $\beta$  are real coefficients. Since

$$B^{r\dagger}B^r = \sigma_0[1 + 2\alpha_{22}(p_x^2 + p_y^2) + (2\alpha_{21} + \beta_{01}^2 + \beta_{11}^2 + \beta_{31}^2)p_z^2] + \mathcal{O}(p^3). \tag{A32}$$

The normalization condition requires  $\alpha_{22}=0$ ,  $\alpha_{21}=-(\beta_{01}^2+\beta_{11}^2+\beta_{31}^2)/2$ . Using  $d_{0,x,z}$  as local coordinates for SU(2), we obtain the Jacobian determinant

$$\left| \frac{\partial d_{0,x,z}}{\partial p_{x,y,z}} \right| = 4 \left| \begin{array}{ccc} \beta_{01} & \beta_{02} & \beta_{03} \\ \beta_{11} & \beta_{12} & \beta_{13} \\ \beta_{31} & \beta_{32} & \beta_{33} \end{array} \right| \cdot (p_x^2 + p_y^2) + \mathcal{O}(p^3) . \tag{A33}$$

It vanishes at  $\mathbf{p} = 0$ .

We perturbatively move the reference point away from the critical value  $i\sigma_y$ :

$$q_{\text{ref}}(\varepsilon) = ie^{i\frac{\varepsilon}{2}\sigma_z}\sigma_y e^{-i\frac{\varepsilon}{2}\sigma_z} = i\sigma_y + \varepsilon \cdot i\sigma_x + \mathcal{O}(\varepsilon^2), \qquad (A34)$$

where  $\varepsilon$  is a sufficiently small rotation along  $\sigma_z$ . (The following discussions also apply to other rotation axes than  $\sigma_z$ .) For those regular  $\mathbf{k} \notin K^4$  satisfying  $B^r(C_4T \cdot \mathbf{k}) = B^r(\mathbf{k}) = i\sigma_y$ , the full-rank local Jacobians ensure solutions  $\mathbf{p}', \mathbf{p} \sim \varepsilon$  to  $B^r(C_4T \cdot \mathbf{k} + \mathbf{p}') = B^r(\mathbf{k} + \mathbf{p}) = q_{\text{ref}}(\varepsilon)$ . Thus, the contribution to  $\deg[B^r]$  from  $\mathbf{k} \notin K^4$  remains even upon the perturbation, and we only need to examine the contribution from neighborhoods of  $\mathbf{k}_0 \in K^4$ . Suppose  $B^r(\mathbf{k}_0) = i\sigma_y$  ( $\mathbf{k}_0 \in K^4$ ), solutions to the equation  $B^r(\mathbf{k}_0 + \mathbf{p}) = q_{\text{ref}}(\varepsilon)$ , i.e.,

$$\beta_{01}p_z + \beta_{02}(p_x^2 - p_y^2) + 2\beta_{03}p_x p_y = \mathcal{O}(\varepsilon^2) , \qquad (A35)$$

$$\beta_{11}p_z + \beta_{12}(p_x^2 - p_y^2) + 2\beta_{13}p_x p_y = \varepsilon + \mathcal{O}(\varepsilon^2)$$
, (A36)

$$\beta_{31}p_z + \beta_{32}(p_x^2 - p_y^2) + 2\beta_{33}p_x p_y = \mathcal{O}(\varepsilon^2),$$
(A37)

give the split preimages. We expect the solutions to satisfy  $|p_z| \sim \varepsilon$ ,  $|p_{x,y}| \sim \varepsilon^{\frac{1}{2}}$ . Eqs. (A35) and (A37) imply

$$(p_x^2 - p_y^2) \cdot \sin 2\varphi + 2p_x p_y \cdot \cos 2\varphi = \mathcal{O}(\varepsilon^2), \qquad (A38)$$

where  $2\varphi=\arctan\frac{\beta_{02}\beta_{31}-\beta_{32}\beta_{01}}{\beta_{03}\beta_{31}-\beta_{33}\beta_{01}}\in(-\frac{\pi}{2},\frac{\pi}{2}].$  We introduce a coordinate transformation  $p_x=p_1\cdot\cos\varphi+p_2\cdot\sin\varphi,\ p_y=-p_1\cdot\sin\varphi+p_2\cdot\cos\varphi$  such that  $p_x^2-p_y^2=(p_1^2-p_2^2)\cdot\cos2\varphi+2p_1p_2\cdot\sin2\varphi,\ 2p_xp_y=-(p_1^2-p_2^2)\cdot\sin2\varphi+2p_1p_2\cdot\cos2\varphi.$  Then the above equation becomes

$$p_1 p_2 = 0 + \mathcal{O}(\varepsilon^2) \,. \tag{A39}$$

Using the new coordinates, we find two branches of solutions to Eqs. (A35) and (A37):

Curve-I: 
$$p_1 = 0 + \mathcal{O}(\varepsilon^{\frac{3}{2}}), \quad p_z = p_2^2 \cdot \frac{\cos 2\varphi \cdot \beta_{02} - \sin 2\varphi \cdot \beta_{03}}{\beta_{01}} + \mathcal{O}(\varepsilon^2),$$
 (A40)

Curve-II: 
$$p_2 = 0 + \mathcal{O}(\varepsilon^{\frac{3}{2}}), \quad p_z = -p_1^2 \cdot \frac{\cos 2\varphi \cdot \beta_{02} - \sin 2\varphi \cdot \beta_{03}}{\beta_{01}} \beta_{01} + \mathcal{O}(\varepsilon^2). \tag{A41}$$

The remaining Eq. (A36) gives a curve in the  $p_1 = 0$  plane

$$p_1 = 0 + \mathcal{O}(\varepsilon^{\frac{3}{2}}), \quad p_z = \frac{\varepsilon}{\beta_{11}} + p_2^2 \frac{\cos 2\varphi \cdot \beta_{12} - \sin 2\varphi \cdot \beta_{13}}{\beta_{11}} + \mathcal{O}(\varepsilon^2),$$
 (A42)

which may have two or zero crossings with curve-I. Eq. (A36) also gives another curve in the  $p_2 = 0$  plane

$$p_2 = 0 + \mathcal{O}(\varepsilon^{\frac{3}{2}}), \quad p_z = \frac{\varepsilon}{\beta_{11}} - p_1^2 \frac{\cos 2\varphi \cdot \beta_{12} - \sin 2\varphi \cdot \beta_{13}}{\beta_{11}} + \mathcal{O}(\varepsilon^2), \tag{A43}$$

which may have zero or two crossings with curve-II. Thus, the number of solutions to Eqs. (A35) to (A37) is even, and they are regular points because in general the Jacobian determinant (Eq. (A33)) is proportional to  $p_x^2 + p_y^2 \sim |\varepsilon| > 0$ . Therefore, a critical point  $\mathbf{k}_0 \in K^4$  splits into an even number of regular points upon the perturbation Eq. (A34), contributing trivially to  $\deg[B^r]$  mod 2 (Eq. (A28)).

The proof for  $P_3 = 0 \mod 1$  is completed.

## 3. Complexity from $C_2$ sewing matrix

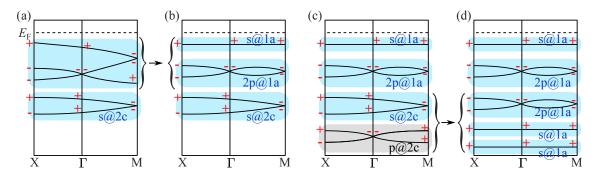


FIG. 4. Adiabatic deformation of the occupied bands. The red  $\pm$  signs indicate the  $C_2$  eigenvalues. Bands shaded in blue form  $C_2$ -BRs, which are BRs of the space group P2 but may exhibit stable topology protected by  $C_4T$  in principle. Bands shaded in grey form  $C_4T$ -BRs, which are in trivial atomic limits. (a) and (b) demonstrate how the occupied bands are deformed into disconnected 1D and 2D blocks. (c) and (d) demonstrate how a generic  $C_2$ -BR is deformed into a  $C_2$ -BR induced from the 1a position by adding auxiliary  $C_4T$ -BRs.

Let us enumerate the elementary BRs - minimal symmetry-allowed atomic limits - of space group P2 and derive their  $C_2$  sewing matrices  $D^r$ . There are four  $C_2$  invariant Wyckoff positions in real space: (0,0,z),  $(\frac{1}{2},\frac{1}{2},z)$ ,  $(\frac{1}{2},0,z)$ ,  $(0,\frac{1}{2},z)$ , where

z is a free parameter ranging from 0 to 1. Without loss of generality, in the following we choose z=0. We use  $|\mathbf{R}+\mathbf{t},\xi\rangle$  to represent a local orbital locating at  $\mathbf{R}+\mathbf{t}$  with  $C_2$  eigenvalue  $\xi=\pm 1$ . Here  $\mathbf{R}$  represents the unit cell and  $\mathbf{t}$  is the corresponding Wyckoff position.  $C_2$  acts on the local orbital as  $C_2|\mathbf{R}+\mathbf{t},\xi\rangle=\xi|-\mathbf{R}-\mathbf{t},\xi\rangle$ . The Bloch states are Fourier transformations

$$|\psi_{\xi}(\mathbf{k})\rangle = \frac{1}{\sqrt{N}} \sum_{\mathbf{R}} e^{i\mathbf{R}\cdot\mathbf{k}} |\mathbf{R} + \mathbf{t}, \xi\rangle ,$$
 (A44)

where N is the system size. They are periodic over the Brillouin zone. One can directly verify that

$$C_{2}|\psi_{\xi}(\mathbf{k})\rangle = \xi \frac{1}{\sqrt{N}} \sum_{\mathbf{R}} e^{i\mathbf{R}\cdot\mathbf{k}} |-\mathbf{R} - \mathbf{t}, \xi\rangle = \xi \frac{1}{\sqrt{N}} \sum_{\mathbf{R}'} e^{i(-\mathbf{R}' - 2\mathbf{t})\cdot\mathbf{k}} |\mathbf{R}' + \mathbf{t}, \xi\rangle = \xi e^{-i2\mathbf{t}\cdot\mathbf{k}} |\psi_{\xi}(C_{2}\mathbf{k})\rangle,$$
(A45)

where  $\mathbf{R}' = -\mathbf{R} - 2\mathbf{t}$ . We can read the  $C_2$  sewing matrix as

$$D_{\mathbf{t},\xi}(\mathbf{k}) = \xi e^{-i2\mathbf{t}\cdot\mathbf{k}} \,. \tag{A46}$$

For later convenience, we introduce Wyckoff position labels for the magnetic space group P4':

$$1a: (0,0,0), 1b: (\frac{1}{2},\frac{1}{2},0), 2c: (\frac{1}{2},0,0), (0,\frac{1}{2},0), (A47)$$

where 1a and 1b is  $C_4T$  symmetric, and the two positions in 2c transform to each under  $C_4T$ .

As explained in the last subsection, since  $C_2$  does not protect any stable topology, the nine  $C_2$  sewing matrices in Eqs. (A22) to (A24) should be identical to that of BRs or fragile topological bands of the space group P2. We hence refer to them as  $C_2$ -BRs (or  $C_2$ -fragile-bands). It might be worth emphasizing that such  $C_2$ -BRs are  $C_4T$ -symmetric, and the  $C_4T$  sewing matrix  $B^r(\mathbf{k})$  could be atomic or topological. For clarity, in the following we refer to the trivial atomic limits respecting the  $C_4T$  symmetry as  $C_4T$ -BRs, whose  $B^r(\mathbf{k})$  matrix is atomic. A  $C_4T$ -BR is by definition a  $C_2$ -BR, but the reverse is not necessarily true. We observe that four of the  $C_2$  sewing matrices in Eqs. (A22) to (A24) (marked red) are consistent with  $C_2$ -BRs. The first (dubbed as 2p@1b) can be obtained from two  $\xi=-1$  states at 1b. The corresponding sewing matrix is

$$D^{r}(\mathbf{k}) = -\sigma_0 \cdot e^{-i(k_x + k_y)}, \qquad (2p@1b).$$
 (A48)

The second (dubbed as 2p@1a) can be obtained from two  $\xi = -1$  states at 1a. The corresponding sewing matrix is

$$D^r(\mathbf{k}) = -\sigma_0 \,, \qquad (2p@1a) \,. \tag{A49}$$

The third (dubbed as p@2c) can be obtained from two  $\xi = -1$  states at 2c, respectively. The corresponding sewing matrix is

$$D^{r}(\mathbf{k}) = \begin{pmatrix} -e^{-ik_{x}} & 0\\ 0 & -e^{-ik_{y}} \end{pmatrix} , \qquad (p@2c) .$$
 (A50)

The fourth (dubbed as s@2c) can be obtained from two  $\xi = 1$  states at 2c, respectively. The corresponding sewing matrix is

$$D^{r}(\mathbf{k}) = \begin{pmatrix} e^{-ik_x} & 0\\ 0 & e^{-ik_y} \end{pmatrix}, \qquad (s@2c).$$
(A51)

One can similarly derive the two 1D  $C_2$ -BRs

$$D^r(\mathbf{k}) = 1 \,, \qquad (s@1a) \,, \tag{A52}$$

$$D^r(\mathbf{k}) = e^{-i(k_x + k_y)}, \qquad (s@1b).$$
 (A53)

The other five sewing matrices (not marked red) in Eqs. (A22) to (A24) must represent  $C_2$ -fragile-bands.

In the last subsection, we have deformed the occupied bands into disconnected blocks where any possible accidental degeneracy is lifted by perturbation terms that do not change the topology. Then we proved that a block does not contribute to  $P_3$  if it is a  $C_2$ -BR (s@1a or 2p@1a) induced from the 1a position, whose  $C_2$  sewing matrix is a constant (Eq. (A25)). Here we show that other  $C_2$ -BRs cannot contribute to  $P_3$  neither. First, as long as the occupied bands as a whole do not exhibit fragile topology, we can always deform them into disconnected blocks where each is a  $C_2$ -BR. Even the occupied bands exhibit a fragile topology as a whole, we can always add auxiliary atomic limits into the occupied bands - without changing the stable topology characterized by  $P_3$  - to trivialize the fragile topology. This is because the defining feature of fragile topology is that it can be trivialized by adding atomic limits, which, as completely localized states, do not contribute to  $P_3$ . Therefore, in order to calculate  $P_3$ , we can always safely assume that the occupied bands can be deformed into disconnected  $C_2$ -BRs.

Second, using the same trick of adding auxiliary atomic BRs, we can always deform the occupied bands into a set of 1D and 2D  $C_2$ -BRs induced from the 1a position. Now we explicitly construct the adiabatic deformations for the  $C_2$ -BRs s@2c, p@2c, 2p@1b, s@1b.

(i) For a 2D block forming a  $C_2$ -BR s@2c, whose  $C_4T$  sewing matrix  $B^r(\mathbf{k})$  may or may not characterize a stable topology, we couple it to an auxiliary  $C_4T$ -BR p@2c, whose  $B^r(\mathbf{k})$  matrix is atomic, such that the four bands  $[s@2c] \oplus [p@2c]$  are equivalent to a  $C_2$ -BR  $[s@1a] \oplus [s@1a] \oplus [2p@1a]$ . To be specific, we write the  $C_2$  sewing matrix of  $[s@2c] \oplus [p@2c]$  as

$$D(\mathbf{k}) = \operatorname{diag} \left( e^{-\mathrm{i}k_x} \ e^{-\mathrm{i}k_y} \ -e^{-\mathrm{i}k_x} \ -e^{-\mathrm{i}k_y} \right) \tag{A54}$$

Notice that a gauge transformation to the Bloch state basis  $|\psi_n'(\mathbf{k})\rangle = |\psi_m(\mathbf{k})\rangle U_{mn}(\mathbf{k})$  changes the  $C_2$  sewing matrix to  $D'(\mathbf{k}) = U^{\dagger}(C_2\mathbf{k}) \cdot D(\mathbf{k}) \cdot U(\mathbf{k})$ . We find the gauge transformation

$$U(\mathbf{k}) = \begin{pmatrix} \frac{1+e^{ik_x}}{2} & 0 & \frac{1-e^{ik_x}}{2} & 0\\ 0 & \frac{1+e^{ik_y}}{2} & 0 & \frac{1-e^{ik_y}}{2}\\ \frac{1-e^{ik_x}}{2} & 0 & \frac{1+e^{ik_x}}{2} & 0\\ 0 & \frac{1+e^{ik_y}}{2} & 0 & \frac{1-e^{ik_y}}{2} \end{pmatrix}$$
(A55)

changes the  $C_2$  sewing matrix to that of a  $C_2$ -BR  $[s@1a] \oplus [s@1a] \oplus [2p@1a]$ :

$$D'(\mathbf{k}) = U^{\dagger}(C_2 \cdot \mathbf{k}) \cdot D(\mathbf{k}) \cdot U(\mathbf{k}) = \operatorname{diag} \begin{pmatrix} 1 & 1 & -1 & -1 \end{pmatrix}.$$
(A56)

Thus, the adiabatic deformation shown in Fig. 4(c) and (d) can be realized by the Hamiltonian

$$(1 - \delta) \cdot \sum_{\mathbf{k}} \sum_{n,m=1}^{4} h_{nm}(\mathbf{k}) |\psi_n(\mathbf{k})\rangle \langle \psi_m(\mathbf{k})| + \delta \cdot \sum_{\mathbf{k}} \sum_{n,m=1}^{4} h'_{nm}(\mathbf{k}) |\psi'_n(\mathbf{k})\rangle \langle \psi'_m(\mathbf{k})|,$$
(A57)

where  $h(\mathbf{k})$  and  $h'(\mathbf{k})$  give the bands shown in Fig. 4(c) and (d), respectively, and  $\delta$  is continuously turned from 0 to 1.

- (ii) For a 2D block forming a  $C_2$ -BR p@2c, we can add an auxiliary  $C_4T$ -BR s@2c and apply the same U (Eq. (A55)) to transform them to a  $C_2$ -BR  $[s@1a] \oplus [s@1a] \oplus [2p@1a]$ . Then an adiabatic deformation similar to Eq. (A57) can be introduced.
- (iii) For a 2D block forming a  $C_2$ -BR 2p@1b, we can add an auxiliary  $C_4T$ -BR  $[s@1b] \oplus [s@1b]$  and transform them to a  $C_2$ -BR  $[2p@1a] \oplus [s@1a] \oplus [s@1a]$ . To be specific, we write the  $C_2$  sewing matrix of  $[2p@1b] \oplus [s@1b] \oplus [s@1b]$  as

$$D(\mathbf{k}) = \operatorname{diag} \left( -e^{-i(k_x + k_y)} - e^{-i(k_x + k_y)} e^{-i(k_x + k_y)} e^{-i(k_x + k_y)} \right). \tag{A58}$$

We find the gauge transformation

$$U(\mathbf{k}) = \begin{pmatrix} \frac{1+e^{i(k_x+k_y)}}{2} & 0 & \frac{1-e^{i(k_x+k_y)}}{2} & 0\\ 0 & \frac{1+e^{i(k_x+k_y)}}{2} & 0 & \frac{1-e^{i(k_x+k_y)}}{2}\\ \frac{1-e^{i(k_x+k_y)}}{2} & 0 & \frac{1+e^{i(k_x+k_y)}}{2} & 0\\ 0 & \frac{1+e^{i(k_x+k_y)}}{2} & 0 & \frac{1-e^{i(k_x+k_y)}}{2} \end{pmatrix}$$
(A59)

changes the  $C_2$  sewing matrix to that of a  $C_2$ -BR  $[2p@1a] \oplus [s@1a] \oplus [s@1a]$ :

$$D'(\mathbf{k}) = U^{\dagger}(C_2 \cdot \mathbf{k}) \cdot D(\mathbf{k}) \cdot U(\mathbf{k}) = \operatorname{diag}(-1 \ -1 \ 1 \ 1) \ . \tag{A60}$$

An adiabatic deformation similar to Eq. (A57) can be introduced then.

(iv) For a 1 D block forming a  $C_2$ -BR s@1b, we can add an auxiliary  $C_4T$ -BR  $[s@1b] \oplus [2p@1b]$  and apply the same U (Eq. (A59)) to transform into a  $C_2$ -BR  $[2p@1a] \oplus [s@1a] \oplus [s@1a]$ . Then an adiabatic deformation similar to Eq. (A57) can be introduced.

Therefore, in terms of the  $C_2$  sewing matrix, the occupied bands can always be deformed into a set of  $C_2$ -BRs induced from the 1a position, whose  $C_2$  sewing matrices are k-independent (Eq. (A25)).

## B. Topological crystal

In this section, we argue that the single-valued magnetic space group P4', where  $(C_4T)^4 = 1$ , protects no clean topological crystalline insulator (TCI) states following the topological crystal method.

Let us first introduce the real space cell decomposition for P4'. Following Ref. [24], an asymmetric unit (AU) is defined as a largest connected open region in three dimensional space that has no overlap with its symmetry partners. The choice of AU is not unique, but we can always choose it as a convex polyhedron. The AU is then copied throughout space using crystalline symmetry operations, and the resulting nonoverlapping union of the copies is denoted A. The complement of the open set A in three dimensional space is a two-skeleton denoted  $X^2$ . A 3-cell is one of the copies of AU in A. A 2-cell is an oriented open segment of a plane separating two 3-cells, which does not overlap with its symmetry partners. Similarly, 1-cells are oriented open segments of lines between different 2-cells that does not overlap with its symmetry partners, and 0-cells are points joining different 1-cells. The construction of n-cells ( $0 \le n \le 3$ ) gives the three dimensional space a cell complex structure. A unit cell with  $C_4T$  symmetry is shown in Fig. 5(a). For simplicity, we define the positive orientation of each 2-cell and 1-cell to be either +x, +y or +z. The red and blue lines  $\alpha, \beta$  are the two  $C_4T$  centers in the unit cell. The three basis lattice vectors are  $a_1, a_2, a_3$ respectively. Fig. 5(b-e) show the cell decomposition of the unit cell. There are four 3-cells, twelve 2-cells, twelve 1-cells, and four 0-cells in each unit cell, which are labeled by  $a_i, b_j, c_k, d_l, 1 \le i, l \le 4, 1 \le j, k \le 12$  respectively. There are also n-cells in the figure that belong to other unit cells, and are thus lattice translations of the labeled n-cells mentioned above. We assume translational symmetry in this section, and treat these n-cells in the same way as their translation partners. For example, the 1-cell shown by the dashed blue line in the second row of Fig. 5(d) is also labeled  $c_1$  since it can be obtained from the 1-cell  $c_1$ in the unit cell (the solid blue line) by a lattice translation  $a_1$ .

Now let us consider how the n-cells are transformed to each other by crystalline symmetries. Apparently, the  $C_4T$  operation transforms  $a_1 \to a_2 \to a_3 \to a_4 \to a_1$  (Fig. 5(b)), so all 3-cells in the lattice are symmetry equivalent. For the 2-cells (Fig. 5(c)),  $C_4T$  operation transforms  $b_1 \to b_2 \to -b_3 \to -b_4 \to b_1$ ,  $b_5 \to -b_7 \to -b_6 \to b_8 \to b_5$ , and  $b_9 \to b_{10} \to b_{11} \to b_{12} \to b_9$ . It is apparent that neither  $C_4T$  nor lattice translation can transform the above three cycles to each other, so there are three distinct symmetry equivalent classes of 2-cells:  $b_{1,2,3,4}$ ,  $b_{5,6,7,8}$ , and  $b_{9,10,11,12}$ . Now let us consider the 1-cells (Fig. 5(d)).  $c_1$  and  $c_4$ lie on the two  $C_4T$  axes  $\alpha, \beta$  respectively. The relative position between them is  $\frac{1}{2}(a_1 + a_2)$ , which is not a lattice vector. It is also apparent that they cannot be transformed to each other by the  $C_4T$  operation. They are also not symmetry equivalent to the other 1-cells since they lie on the only two  $C_4T$  axes, so each of them forms a symmetry equivalent class by itself. The two other 1-cells parallel to z direction are  $c_2$  and  $c_3$ .  $C_4T$  operation transforms  $c_3 \to c_2$ . Since they are obviously not symmetry equivalent to the 1-cells parallel to the xy plane,  $c_{2,3}$  form a symmetry equivalent class. Among the 1-cells parallel to the xyplane,  $C_4T$  operation transforms  $c_5 \to c_{11} \to -c_6 \to -c_{12} \to c_5$ , and  $c_9 \to -c_8 \to -c_{10} \to c_7 \to c_9$ , but cannot relate the above two cycles. Therefore,  $c_{5,6,11,12}$  and  $c_{7,8,9,10}$  form two distinct symmetry equivalent classes of 1-cells. In summary, the twelve 1-cells can be divided into five different symmetry equivalent classes:  $c_1, c_4, c_{2.3}, c_{5.6,11,12}$  and  $c_{7.8,9,10}$ . The four 0-cells  $d_{1,2,3,4}$  (Fig. 5(e)) are ends of the four 1-cells that are parallel to z direction  $c_{1,2,3,4}$  respectively, so following above discussions, they can be divided into three different symmetry equivalent classes:  $d_1, d_4, d_{2,3}$ . In summary, there are 1, 3, 5, 3 distinct symmetry equivalent classes of 3, 2, 1, 0-cells respectively. In Fig. 5(c-e), symmetry equivalent n-cells are shown in the same color to emphasize their relationships.

Following Refs. [21, 22, 24], a topological crystal is defined as a gapped decoration of lower-dimensional TIs on the n-cells ( $n \le 2$ ) that respects the crystalline symmetry. Now let us repeat the argument that a TCI state can always be adiabatically connected to a topological crystal. Since there is no 3D strong TIs protected by local symmetry in the considered symmetry class A, one can always trivialize the AU by deforming it into a set of occupied local orbitals. This is always accessible provided  $\xi \ll a_{AU}$ , where  $\xi$  is the characteristic correlation length of the TCI ground state, and  $a_{AU}$  is the linear size of the AU. Since TCI ground states are short range correlated, it is reasonable to expect that by adding a fine enough mesh of trivial degrees of freedom in the AU,  $\xi$  can be made as small as required, while  $a_{AU}$  remains unchanged.  $\xi \ll a_{AU}$  is thus satisfied, and the desired adiabatic path can be found. The adiabatic path is then copied throughout space using crystalline symmetry to trivialize the open set  $\mathcal{A}$ . It is obvious that such a copy always respects the crystalline symmetry. After the above adiabatic deformation, the topologically nontrivial elements can only lie on the two-skeleton  $X^2$ , and can be decomposed to lower-dimensional TIs decorated on n-cells,  $n \le 2$ . Ref. [24] shows that a full classification of all TCIs with spin-orbit coupling and time reversal symmetry can be obtained by topological crystals, proving the validity of the above argument. Since symmetry class A has no 0- and 1-dimensional TIs, we only consider decorations of Chern insulators on the 2-cells.

In a cell complex structure, the boundary of an n-cell can be expanded in terms of oriented (n-1)-cells. For examples:  $\partial a_1 = b_7 + b_2 - b_1 - b_6$  for 3-cells,  $\partial b_1 = -c_2 + c_4$ ,  $\partial b_5 = c_1 - c_2$ , and  $\partial b_9 = c_6 + c_{11} - c_8 - c_9$  for 2-cells,  $\partial c_1 = d_1 - d_1 = 0$ ,  $\partial c_2 = 0$ ,  $\partial c_4 = 0$ ,  $\partial c_5 = -d_1 + d_2$ , and  $\partial c_7 = -d_3 + d_4$  for 1-cells. Such boundary mappings will be used for the gluing conditions and bubble equivalence of the topological crystal.

Concerning decorations of Chern insulators on 2-cells, the gluing condition requires an equal number of chiral modes propagating in opposite directions on each 1-cell so that it is possible for them to be locally gapped. Here we show that such conditions, together with the crystalline symmetry, make restrictions on possible decorations. A decoration of Chern insulators on 2-cells in Fig. 5(c) is described by twelve integers  $C_{b_j} \in \mathbb{Z}, 1 \leq j \leq 12$ , which are the Chern numbers of decorated

Chern insulators on the 2-cells  $b_j$ , with the same orientation as discussed above. Using the crystalline symmetry and the fact that time reversal operation reverses the Chern number, the description can be simplified to three integers  $C_1, C_2, C_3 \in \mathbb{Z}$ :  $C_{b_1} = -C_{b_2} = -C_{b_3} = C_{b_4} = C_1$ ,  $C_{b_5} = C_{b_7} = -C_{b_6} = -C_{b_8} = C_2$ , and  $C_{b_9} = -C_{b_{10}} = C_{b_{11}} = -C_{b_{12}} = C_3$ . Since there are five different symmetry equivalent classes of 1-cells, there are also five symmetry inequivalent gluing conditions (for  $c_1, c_2, c_4, c_5, c_7$  respectively):

$$C_{b_5} - C_{b_7} - C_{b_6} + C_{b_8} = 0$$

$$-C_{b_1} + C_{b_3} + C_{b_6} - C_{b_5} = 0$$

$$C_{b_1} + C_{b_2} - C_{b_3} - C_{b_4} = 0$$

$$C_{b_{12}} - C_{b_{11}} = 0$$

$$-C_{b_{12}} + C_{b_{11}} = 0$$
(B1)

where we have used translational symmetry implicitly. The first and third rows are automatically satisfied, the second row requires  $C_1 = -C_2$ , and the last two rows require  $C_3 = 0$ . We hence conclude that decorations of Chern insulators with  $C_{b_1} = -C_{b_2} = -C_{b_3} = C_{b_4} = -C_{b_5} = C_{b_8} = C_{b_6} = -C_{b_7} = C \in \mathbb{Z}$ ,  $C_{b_9} = C_{b_{10}} = C_{b_{11}} = C_{b_{12}} = 0$  are the only possible decorations that satisfy both the crystalline symmetry and gluing conditions.

Since Chern insulators have a  $\mathbb{Z}$  classification, one can make a decoration with C any nonzero integer. However, here we show that some of the decorations can be adiabatically connected to the trivial C=0 case by creating Chern bubbles from vacuum and locally annihilating Chern insulators with opposite Chern numbers, a process called "bubble equivalence" in Ref. [24]. Create a bubble of a C=-1 state within the AU as well as its symmetry partners, as shown in Fig. 5(f). Expand these bubbles until they are touching the 2-cells, the resulted decoration is given by

$$-\partial a_1 + \partial a_2 - \partial a_3 + \partial a_4 = 2b_1 - 2b_2 - 2b_3 + 2b_4 - 2b_5 - 2b_7 + 2b_6 + 2b_8.$$
 (B2)

Here the integer coefficients of the 2-cells represent the corresponding Chern numbers. The above equation gives a C=2 decoration. Creating bubbles with other Chern numbers yield all  $C \in$  even decorations. Therefore, after modulo the bubble equivalence, we obtain a  $\mathbb{Z}_2$  classification represented by the C=0,1 decorations.

Now we show that the C=1 decoration is equivalent to the decoration in Fig.1(c) in the main text. Unlike  $c_1, c_4$ , the four chiral modes on  $c_2, c_3$  have only  $C_2$  symmetry, and can be paired and gapped. Consider the dimerization shown in Fig. 5(g), which effectively joins Chern insulators decorated on  $b_5$  with  $b_1$ ,  $b_3$  with  $b_6$ ,  $b_4$  with  $b_8$ , and  $b_2$  with  $b_7$ . After a deformation respecting  $C_4T$  symmetry, we arrive at the same decoration as shown in Fig.1(c) of the main text, whose low energy physics is realized by the lattice model.

The above discussion seems apply to both  $(C_4T)^4 = 1$  and -1 cases. However, when  $(C_4T)^4 = 1$ , the C = 1 decoration must be gapless according to the discussion in the main text. Therefore, no gapped topological state can be constructed in the framework of topological crystal, suggesting a trivial classification in the clean limit.

We now show that the C=1 decoration can be gapped if  $(C_4T)^4=-1$ . Consider four chiral modes 1,2,3,4 on a hinge, which are transformed as  $1\to 2\to 3\to 4\to 1$  by the  $C_4T$  operation, and are propagating in +z,-z,+z,-z direction respectively with velocity v. Let us span the four-by-four Hilbert space with two sets of Pauli matrices  $\sigma_{0,x,y,z},\tau_{0,x,y,z}$ , where  $\{\tau_z,\sigma_z\}=\{+,+\},\{+,-\},\{-,+\},\{-,-\}$  denote chiral mode 1,2,3,4 respectively. The four-by-four Hamiltonian of the four modes is

$$H(k_z) = vk_z \tau_0 \sigma_z \tag{B3}$$

Consider the  $(C_4T)^4 = -1$  symmetry  $C_4T = D(C_4T)K$ , where K is the complex conjugation, and

$$D(C_4T) = \begin{pmatrix} 0 & 0 & 0 & 1\\ i & 0 & 0 & 0\\ 0 & -1 & 0 & 0\\ 0 & 0 & -i & 0 \end{pmatrix}, \qquad D(C_4T)D^*(C_4T)D(C_4T)D^*(C_4T) = -1$$
(B4)

Since  $D(C_4T)H^*(k_z)D^\dagger(C_4T)=H(-k_z),\ D(C_4T)(\tau_x\sigma_x)^*D^\dagger(C_4T)=\tau_0\sigma_y,\ \text{and}\ D(C_4T)(\tau_0\sigma_y)^*D^\dagger(C_4T)=\tau_x\sigma_x,\ \text{a}$  mass term  $m(\tau_x\sigma_x+\tau_0\sigma_y)$  can be added to  $H(k_z)$  without breaking the  $(C_4T)^4=-1$  symmetry. Since  $\tau_0\sigma_z,\tau_x\sigma_x$  and  $\tau_0\sigma_y$  anti-commute with one another, the two pairs of energy bands are  $E_\pm(k_z)=\pm\sqrt{(vk_z)^2+2m^2}$ . This allows the construction of a topological crystal for a clean axion insulator if  $(C_4T)^4=-1$ , consistent with the previous discussions in Refs. [45, 50].

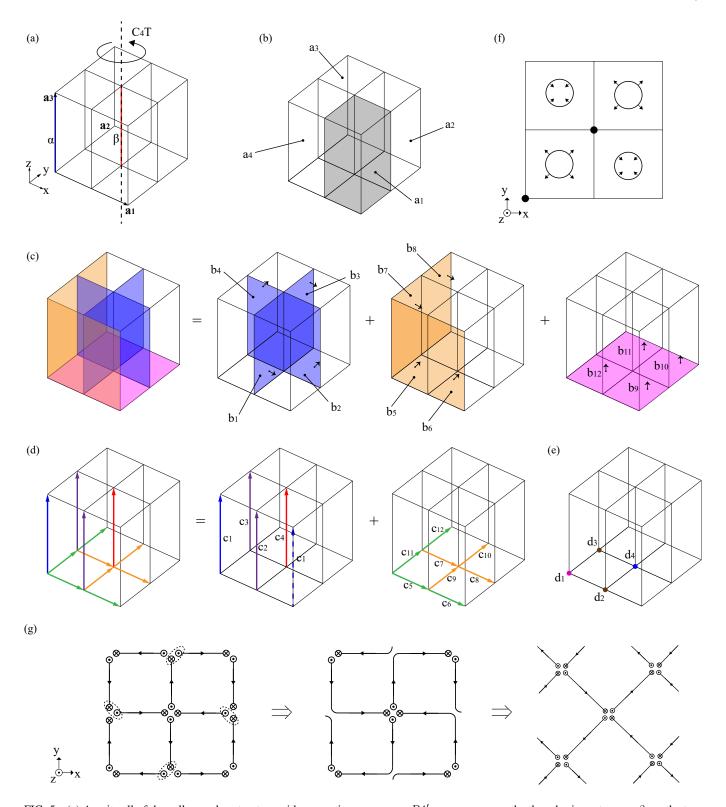


FIG. 5. (a) A unit cell of the cell-complex structure with magnetic space group P4'.  $a_1$ ,  $a_2$ ,  $a_3$  are the three basis vectors.  $\alpha$ ,  $\beta$  are the two  $C_4T$  axes in the unit cell. In the paragraph, " $C_4T$  operation" refers to the one shown by the arrow unless otherwise specified. (b) The four 3-cells in the unit cell. The 3-cell  $a_1$  is shown in grey,  $a_{2,3,4}$  are transformed from  $a_1$  by  $C_4T$  around  $\beta$  axis. (c) The twelve 2-cells in the unit cell. (d) The twelve 1-cells in the unit cell. The dashed blue line is the  $a_1$  translation of the solid blue line, so both are labeled  $c_1$ . The positive orientation of 2-cells and 1-cells are either +x, +y or +z, as shown by the arrows in (c) and (d). (e) The four 0-cells in the unit cell. The n-cells in (c-e) with same color are equivalent up to crystalline symmetry operations. (f) (upper right) By creating a Chern bubble (the oriented circle) with C=-1 in the AU (3-cell  $a_1$ ) and its symmetry partners and expanding the Chern bubbles to the boundaries of 3-cells, we arrive at the decoration with C=2, demonstrating the "bubble equivalence" of  $C\in even$  to C=0. (g) The C=1 decoration is equivalent to Fig.1(c) in the main text up to gapping paired chiral edges and a spatial deformation.

#### C. The lattice model

## 1. Model and symmetry

Here we give a complete description of the lattice model given in Eq. (2) in the main text. As shown in Fig. 6(a), a unit cell has 8 orbitals. We use three sets of Pauli matrices  $\rho_{0,x,y,z}$ ,  $\tau_{0,x,y,z}$ ,  $\sigma_{0,x,y,z}$  to span the eight-by-eight Hilbert space.  $\rho_z=1,-1$  correspond to the two squares in a unit cell,  $\tau_z=1,-1$  further labels the two columns in each square, and  $\sigma_z=1,-1$  labels the two sites within each column. The Hamiltonian in momentum space takes the form

$$H(\mathbf{k}) = (m + 2t - 2t\cos k_z)\rho_x\tau_x\sigma_x + 2t\sin k_z\rho_z\tau_z\sigma_z$$

$$+ \gamma(\cos\frac{k_x}{2}\rho_0\tau_x\sigma_0 - \sin\frac{k_x}{2}\rho_0\tau_y\sigma_0 + \cos\frac{k_y}{2}\rho_0\tau_0\sigma_x - \sin\frac{k_y}{2}\rho_0\tau_0\sigma_y)$$

$$+ \lambda(\cos\frac{k_x}{2}\cos\frac{k_y}{2}\rho_0\tau_x\sigma_x + \sin\frac{k_x}{2}\sin\frac{k_y}{2}\rho_0\tau_y\sigma_y - \sin\frac{k_x}{2}\cos\frac{k_y}{2}\rho_0\tau_y\sigma_x - \cos\frac{k_x}{2}\sin\frac{k_y}{2}\rho_0\tau_x\sigma_y)$$
(C1)

The first row of Eq. (C1) defines four pairs of chiral and anti-chiral states in the z-direction. For example, the 1st and 8th orbitals span the Hamiltonian  $(m+2t-2t\cos k_z)\sigma_x+2t\sin k_z\sigma_z$ , where  $\sigma_z=1,-1$  correspond to 1st and 8th orbitals, respectively. When m is small, it reduces to a Dirac Hamiltonian around  $k_z=0$ :  $(m+tk_z^2)\sigma_x+2tk_z\sigma_z+\mathcal{O}(k_z^3)$ , and has a large gap around  $k_z=\pi$ . Thus, the 1st and 8th orbitals simulate a pair of anti-chiral and chiral edge modes of a Chern block shown in Fig. 1(c) of the main text. m is the coupling between two edges, and it should approach zero if the Chern block is sufficiently large. In this work we use m as a tuning parameter. Similarly, 2nd and 7th orbitals, 3rd and 6th orbitals, 4th and 5th orbitals form the other three pairs of anti-chiral and chiral states, respectively.  $\gamma$  in the second row of Eq. (C1) is the hopping between nearest neighbors within each square.  $\lambda$  in the third row of Eq. (C1) is the hopping along the diagonals of each square.

We have adopt a symmetric gauge for Eq. (C1). In this gauge, the eight Bloch bases are defined as

$$|\phi_{\alpha,\mathbf{k}}\rangle = \frac{1}{\sqrt{N}} \sum_{\mathbf{R}} e^{i\mathbf{k}\cdot(\mathbf{R}+\mathbf{t}_{\alpha})} |\mathbf{R},\alpha\rangle$$
 (C2)

where  $|\mathbf{R}\alpha\rangle$  ( $\alpha=1\cdots 8$ ) is a local orbital locating at  $\mathbf{R}+\mathbf{t}_{\alpha}$ , N is the number of unit cells,  $\mathbf{R}$  sums over lattice vector, and  $\mathbf{t}_{\alpha}$  is the sublattice vector for the  $\alpha$ -th orbital. We choose

$$\mathbf{t}_{1} = (\delta, \delta, 0), \quad \mathbf{t}_{2} = (\delta, \frac{1}{2} - \delta, 0), \quad \mathbf{t}_{3} = (\frac{1}{2} - \delta, \delta, 0), \quad \mathbf{t}_{4} = (\frac{1}{2} - \delta, \frac{1}{2} - \delta, 0),$$

$$\mathbf{t}_{5} = (\frac{1}{2} + \delta, \frac{1}{2} + \delta, 0), \quad \mathbf{t}_{6} = (\frac{1}{2} + \delta, -\delta, 0), \quad \mathbf{t}_{7} = (-\delta, \frac{1}{2} + \delta, 0), \quad \mathbf{t}_{8} = (-\delta, -\delta, 0),$$
(C3)

where  $\delta>0$  is a small quantity. In Fig. 6 we use a finite  $\delta$  for illustration. But in practical calculation we take the  $\delta\to0$  limit for simplicity.  $H(\mathbf{k})$  is the Hamiltonian matrix on the Bloch basis, i.e.,  $H_{\alpha\beta}(\mathbf{k})=\langle\phi_{\alpha,\mathbf{k}}|\hat{H}|\phi_{\beta,\mathbf{k}}\rangle$ . The  $\cos\frac{k_{x,y}}{2}$  and  $\sin\frac{k_{x,y}}{2}$  factors in Eq. (C1) come from phase factors  $e^{i\mathbf{k}\cdot(\mathbf{t}_{\alpha}-\mathbf{t}_{\beta})}$  appearing along hoppings between the  $\alpha$ -th and  $\beta$ -th orbitals. The Bloch basis satisfies a twisted boundary condition over the Brillouin zone

$$|\phi_{\alpha,\mathbf{k}+\mathbf{G}}\rangle = |\phi_{\beta,\mathbf{k}}\rangle V_{\beta\alpha}(\mathbf{G}), \qquad V_{\beta\alpha}(\mathbf{G}) = \delta_{\alpha\beta}e^{i\mathbf{G}\cdot\mathbf{t}_{\alpha}},$$
 (C4)

where implicit summation over repeated indices is assumed. It follows that  $H(\mathbf{k})$  satisfies

$$H(\mathbf{k} + \mathbf{G}) = V^{\dagger}(\mathbf{G})H(\mathbf{k})V(\mathbf{G}). \tag{C5}$$

 $V(\mathbf{G})$  is usually referred to as the embedding matrix.

Now we summarize the symmetries of  $H(\mathbf{k})$ . First, we show that  $H(\mathbf{k})$  breaks the time-reversal symmetry (TRS). As explained in the above two paragraphs, the orbitals  $|\mathbf{0},1\rangle$   $|\mathbf{0},8\rangle$  mimic a pair of anti-chiral and chiral modes at the same position. Thus, TRS, if existed, must interchange  $|\mathbf{0},1\rangle$  and  $|\mathbf{0},8\rangle$ . For the same reason, TRS must send  $|\mathbf{R},\alpha\rangle$  to  $|\mathbf{R},9-\alpha\rangle$ . Consider the hopping  $\lambda$  between  $|\mathbf{0},1\rangle$ ,  $|\mathbf{0},2\rangle$ , TRS would transform it to a hopping between  $|\mathbf{0},8\rangle$ ,  $|\mathbf{0},7\rangle$ , which does not exist in the model (Fig. 6(a)). The model instead has a hopping between  $|\mathbf{0},7\rangle$  and  $|\mathbf{0}\mathbf{1}\mathbf{0},8\rangle$ , wherein the latter is in another unit cell. We find that  $H(\mathbf{k})$  enjoys a symmetry group generated by

$$H(\mathbf{k}) = \mathcal{D}(P) \cdot H(-\mathbf{k}) \cdot \mathcal{D}^{\dagger}(P), \qquad \mathcal{D}(P) = \rho_x \tau_x \sigma_x, \qquad P = \{-1|\mathbf{0}\},$$
 (C6)

$$H(-k_y, k_x, k_z) = \mathcal{D}(\widetilde{C}_4) \cdot H(\mathbf{k}) \cdot \mathcal{D}^{\dagger}(\widetilde{C}_4), \qquad \mathcal{D}(\widetilde{C}_4) = \rho_x \begin{pmatrix} 0 & 0 & 1 & 0 \\ 1 & 0 & 0 & 0 \\ 0 & 0 & 0 & 1 \\ 0 & 1 & 0 & 0 \end{pmatrix}, \qquad \widetilde{C}_4 = \{4_{001} | 0\frac{1}{2}0 \}, \qquad (C7)$$

$$H(-k_x, k_y, k_z) = \mathcal{D}(\widetilde{M}_x) \cdot H(\mathbf{k}) \cdot \mathcal{D}^{\dagger}(\widetilde{M}_x), \qquad \mathcal{D}(\widetilde{M}_x) = \rho_x \tau_x \sigma_0, \qquad \widetilde{M}_x = \{m_{100} | 0\frac{1}{2}0\}$$
 (C8)

$$H(-\mathbf{k}) = \mathcal{D}(\widetilde{T}) \cdot H^*(\mathbf{k}) \cdot \mathcal{D}^{\dagger}(\widetilde{T}), \qquad \mathcal{D}(\widetilde{T}) = \rho_x \tau_0 \sigma_0, \qquad \widetilde{T} = \{1' | \frac{1}{2} \frac{1}{2} 0\}.$$
 (C9)

Here  $\{p^{(i)}|\tau\}$  is the Seitz symbol for spatial operations, and a prime in the superscript of p represent a time-reversal operation following the point group operation p. We adopt the convention of the MGENPOS program of the Bilbao Crystallographic Server [71, 72]. P is an inversion centered at the origin,  $\widetilde{C}_4$  is a four-fold rotation centered at  $(-\frac{1}{4}\frac{1}{4}0)$ ,  $\widetilde{M}_x$  is a glide mirror with respect to the plane (0, y, z), and  $\widetilde{T}$  is a magnetic translation. These operations generate the single-valued magnetic space group  $P_C 4/nbm$  (#125.373 in the BNS setting). This group also has  $C_4 T = \{1|0\bar{1}0\} \cdot \widetilde{T} \cdot \widetilde{C}_4 = \{4'_{001}|\frac{1}{2}00\}, S_4 = P \cdot \widetilde{C}_4^3 = 10^{-3} \cdot \widetilde{C}_4 = \{4'_{001}|\frac{1}{2}00\}, S_4 = P \cdot \widetilde{C}_4^3 = 10^{-3} \cdot \widetilde{C}_4 = 10^{-3} \cdot$ are  $(\frac{1}{4},y,z)$  and (x,y,0), respectively.  $\widetilde{M}_z$  is a glide mirror with respect to the (x,y,0) plane. For later convenience, we also derive the representation of  $S_4$ 

$$\mathcal{D}(S_4) = \mathcal{D}(P) \cdot \mathcal{D}^3(\widetilde{C}_4) = \rho_0 \begin{pmatrix} 0 & 0 & 1 & 0 \\ 1 & 0 & 0 & 0 \\ 0 & 0 & 0 & 1 \\ 0 & 1 & 0 & 0 \end{pmatrix} . \tag{C10}$$

Here we also summarize the maximal Wykcoff positions and their magnetic point groups:

$$2a: \quad (\frac{1}{4},\frac{1}{4},0), \quad (\frac{3}{4},\frac{3}{4},0), \quad 4'/m'm'm, \qquad \qquad 2b: \quad (\frac{1}{4},\frac{1}{4},\frac{1}{2}), \quad (\frac{3}{4},\frac{3}{4},\frac{1}{2}), \quad 4'/m'm'm \; , \qquad \quad \text{(C11)}$$

$$2c: \quad (\frac{1}{4},\frac{3}{4},0), \quad (\frac{3}{4},\frac{1}{4},0), \quad 4/m'm'm', \qquad \qquad 2d: \quad (\frac{1}{4},\frac{3}{4},\frac{1}{2}), \quad (\frac{3}{4},\frac{1}{4},\frac{1}{2}), \quad 4/m'm'm' \; , \qquad \quad (\text{C12})$$

$$4e: \quad (0,0,\frac{1}{2}), \quad (\frac{1}{2},0,\frac{1}{2}), \quad (0,\frac{1}{2},\frac{1}{2}), \quad (\frac{1}{2},\frac{1}{2},\frac{1}{2}), \qquad m'.mm' \; , \tag{C13}$$

$$4f: \quad (0,0,0), \quad (\frac{1}{2},0,0), \quad (0,\frac{1}{2},0), \quad (\frac{1}{2},\frac{1}{2},0), \qquad m'.mm' \ . \tag{C14}$$

In our convention, the origin is shifted by  $(\frac{1}{2},0,0)$  from that on the Bilbao Crystallographic Server. Let us examine whether Eq. (C1) has a chiral symmetry:  $S \cdot H(\mathbf{k}) \cdot S = -H(\mathbf{k})$  with S being a unitary matrix satisfying  $S^2=1$ . For S to anti-commute with the  $\rho_0\tau_0\sigma_{x,y}$  terms in the second row of Eq. (C1), S must be proportional to  $\sigma_z$ . Similarly, for S to anti-commute with the  $\rho_0 \tau_{x,y} \sigma_0$  terms in the second row, S must be proportional to  $\tau_z$ . Then, S could be a linear combination of  $\rho_{0,x,y,z}\tau_z\sigma_z$ , all of which commute with the  $\lambda$  terms of Eq. (C1). If  $\lambda=0$ ,  $H(\mathbf{k})$  has an accidental chiral  $S=\rho_y\tau_z\sigma_z$ . Being off-diagonal in the  $\rho_z=\pm 1$  basis, S is non-local in real space and hence will be broken by disorder potentials. Therefore, either a finite  $\lambda$  or disorder potential will break the accidental chiral symmetry.

Let us examine whether Eq. (C1) has a particle-hole symmetry:  $C \cdot H^*(\mathbf{k}) \cdot C^{\dagger} = -H(-\mathbf{k})$  with C being a unitary matrix satisfying  $C \cdot C^* = \pm 1$ . Because of the T symmetry of  $H(\mathbf{k})$  (Eq. (C9)), the existence of C symmetry would automatically imply the presence of a chiral symmetry  $S = \rho_x \cdot C$  (up to a U(1) phase factor), and vice versa. According to the discussions in the last paragraph,  $H(\mathbf{k})$  would have an accidental  $C = \rho_z \tau_z \sigma_z$  when  $\lambda = 0$ . Either a finite  $\lambda$  or on-site disorder potentials can break this accidental particle-hole symmetry.

In the following, we keep  $t=2, \gamma=1, \lambda=0.01$  fixed and discuss how m changes the band structure of the system. For convenience, we define the high symmetry momenta

$$\begin{array}{lll} \Gamma: \; (0,0,0), & \quad X: \; (\pi,0,0), & \quad M: \; (\pi,\pi,0) \\ Z: \; (0,0,\pi), & \quad R: \; (\pi,0,\pi), & \quad A: \; (\pi,\pi,\pi) \; . \end{array}$$

and plot the energy bands along the high-symmetry line  $\Gamma - X - M - \Gamma - Z - R - A - Z$ . Let us start with the m = 0 limit. As shown in Fig. 6(b), the low-energy bands are quasi-1D around the  $k_z = 0$  plane, which is consistent with the picture of decoupled helical modes explained below Eq. (C1). A small finite m>0 drives the system to a nodal line semi-metal phase, as illustrated in Fig. 6(c). The nodal line is protected by the  $P\widetilde{T}$  symmetry and pinned in the  $k_z=0$  plane by the glide symmetry

 $\widetilde{M}_z=\{m_{001}|\frac{1}{2}\frac{1}{2}0\}$ . When m increases, the nodal line shrinks towards the  $\Gamma$  point (Fig. 6(d-g)). At a critical value  $m=2\gamma$ , the nodal line shrinks to a point at  $\Gamma$  (Fig. 6(h)). Further increasing m will open a gap (Fig. 6(i)). This gap is trivial since it is adiabatically connected to the  $m\to\infty$  limit, which describes an atomic insulator with dimers formed by nearest neighbors. Now let us discuss the m<0 case. Rather similarly, a small  $-2\gamma < m<0$  also drives the system to a nodal-line semi-metal, whose nodal-line is pinned on the  $k_z=0$  plane and shrinks as |m| increases, finally becoming the  $\Gamma$  point when  $m=-2\gamma$ . Tuning m to  $-2\gamma-\epsilon$ , where  $\epsilon$  is a small positive number, will also open a gap when  $t>\gamma$ . However, this state is not adiabatically connected to the  $m\to-\infty$  limit. To see this, notice that when  $k_z=\pi+\delta k_z, \delta k_z\ll\pi$ , the first row of Eq. (C1) can be expanded as  $(m+4t-t\delta k_z^{\ 2})\rho_x\tau_x\sigma_x-2t\delta k_z\rho_z\tau_z\sigma_z$ , which defines four pairs of chiral and anti-chiral states near  $k_z=\pi$  when m+4t is small (see the explanation below Eq. (C1)). Similar to the above discussions, the band structure is quasi-1D on  $k_z=\pi$  when m=-4t, and is a nodal-line semi-metal with a nodal line pinned on the  $k_z=\pi$  plane when  $0<|m+4t|<2\gamma$ . In this paper, we take  $t=2>\gamma=1$ , which means there are no overlap between the two gapless regions  $|m|<2\gamma$  and  $|m+4t|<2\gamma$ . Since the low energy physics of the above two nodal-line semi-metals are similar to each other, an intrinsic STI phase should emerge near  $k_z=\pi$ , when  $|m+4t|\ll\gamma$  and  $C_4T$  preserving disorder is introduced, similar to intrinsic STI phase near  $k_z=0$  when  $|m|\ll\gamma$ , as illustrated in Fig. 2(b) of the main text. Since our purpose is to demonstrate the existence of an intrinsic STI phase, we will focus on  $|m|\ll\gamma$  and  $k_z\approx0$  in following discussions and numerical calculations.

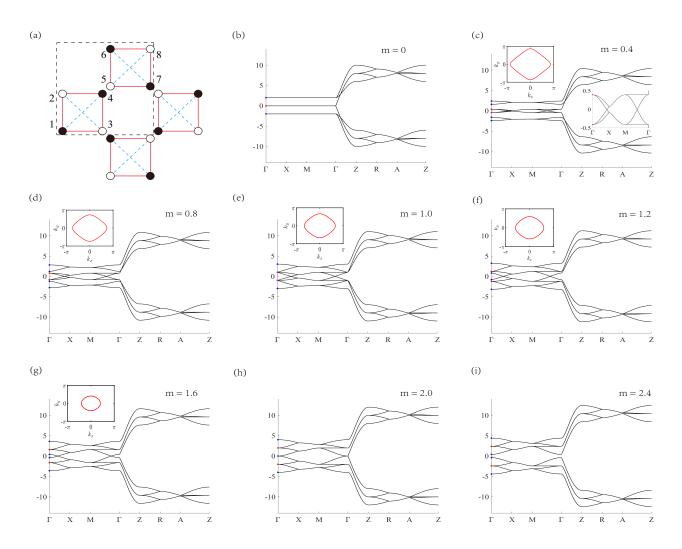


FIG. 6. (a). The lattice model with eight orbitals per unit cell. Orbitals 6, 7, 8 in unit cells (010), (100), and (110) (rather than that in home unit cells) are shown for the convenience of illustration. In each cell,  $\rho=\pm 1$  labels a square (e.g.  $\rho=1\to {\rm sites}\ \{1,2,3,4\}$ ),  $\tau=\pm 1$  labels a column (e.g.  $\rho=1,\tau=1\to {\rm sites}\ \{1,2\}$ ), and  $\sigma=\pm 1$  labels a site (e.g.  $\rho=1,\tau=1,\sigma=1\to {\rm site}\ 1$ ). (b-i). The band structure of the lattice model with  $t=2,\gamma=1,\lambda=0.01$  and different m. Upper left insets of (c-g) show the position of the nodal-line on the  $k_z=0$  plane. Right inset of (c) shows the details of low-energy band structure at  $k_z=0$ . Blue and red dots at  $\Gamma$  label  $C_2$  eigenstates with eigenvalue  $\pm 1$  respectively. When  $m\ll \gamma$ , the low energy band structure is dominated by the  $C_2=-1$  sector.

## 2. Low energy states

When m is zero, low energy states are the quasi-1D helical modes around  $k_z = 0$ . In this subsection, we will derive a low energy  $k \cdot p$  expansion for the helical modes. For a finite but small m, these modes form a nodal line semi-metal. We will also discuss the transition from the nodal line semi-metal to a trivial band insulator when m becomes larger.

We view  $H(k_z = 0)$  as a 2D Hamiltonian. When m = 0, it decomposes into decoupled molecules on the red squares shown in Fig. 6(a). The Hamiltonian around  $k_z = 0$  reduces to

$$H(\mathbf{k}) = 2tk_{z} \cdot \rho_{z}\tau_{z}\sigma_{z} + \rho_{0} \begin{pmatrix} 0 & \gamma e^{i\frac{k_{y}}{2}} & \gamma e^{i\frac{k_{x}}{2}} & \lambda e^{i\frac{k_{x}+k_{y}}{2}} \\ \gamma e^{-i\frac{k_{y}}{2}} & 0 & \lambda e^{i\frac{k_{x}-k_{y}}{2}} & \gamma e^{i\frac{k_{x}}{2}} \\ \gamma e^{-i\frac{k_{x}}{2}} & \lambda e^{-i\frac{k_{x}-k_{y}}{2}} & 0 & \gamma e^{i\frac{k_{y}}{2}} \\ \lambda e^{-i\frac{k_{x}+k_{y}}{2}} & \gamma e^{-i\frac{k_{x}}{2}} & \gamma e^{-i\frac{k_{y}}{2}} & 0 \end{pmatrix} + \mathcal{O}(k_{z}^{2})$$

$$= 2tk_{z} \cdot \rho_{z}\tau_{z}\sigma_{z} + \rho_{0} \cdot \operatorname{diag}(1 \ e^{i\frac{k_{y}}{2}} \ e^{i\frac{k_{x}}{2}} \ e^{i\frac{k_{x}+k_{y}}{2}})^{\dagger} \cdot \begin{pmatrix} 0 & \gamma & \gamma & \lambda \\ \gamma & 0 & \lambda & \gamma \\ \gamma & \lambda & 0 & \gamma \\ \lambda & \gamma & \gamma & 0 \end{pmatrix} \cdot \operatorname{diag}(1 \ e^{i\frac{k_{x}}{2}} \ e^{i\frac{k_{x}+k_{y}}{2}}) + \mathcal{O}(k_{z}^{2}), \quad (C15)$$

where the k-independent matrix in the middle represent the local Hamiltonian of each molecule. We find the eigenvectors and eigenvalues at  $k_z = 0$ :

$$u_{\xi=-1,\eta=\pm 1,n=1}(\mathbf{k}) = \frac{1}{2} \begin{pmatrix} \frac{1+\eta}{2} \\ \frac{1-\eta}{2} \cdot e^{i\frac{k_x+k_y}{2}} \end{pmatrix} \otimes \begin{pmatrix} 1 \\ ie^{-i\frac{k_y}{2}} \\ -ie^{-i\frac{k_x}{2}} \\ -e^{-i\frac{k_x+k_y}{2}} \end{pmatrix}, \qquad E = -\lambda ,$$
 (C16)

$$u_{\xi=-1,\eta=\pm 1,n=2}(\mathbf{k}) = \frac{1}{2} \begin{pmatrix} \frac{1+\eta}{2} \\ \frac{1-\eta}{2} \cdot e^{i\frac{k_x+k_y}{2}} \end{pmatrix} \otimes \begin{pmatrix} 1 \\ -ie^{-i\frac{k_y}{2}} \\ ie^{-i\frac{k_x}{2}} \\ -e^{-i\frac{k_x+k_y}{2}} \end{pmatrix}, \qquad E = -\lambda ,$$
 (C17)

$$u_{\xi=1,\eta=\pm 1,n=1}(\mathbf{k}) = \frac{1}{2} \begin{pmatrix} \frac{1+\eta}{2} \\ \frac{1-\eta}{2} \cdot e^{i\frac{k_x+k_y}{2}} \end{pmatrix} \otimes \begin{pmatrix} 1 \\ -e^{-i\frac{k_y}{2}} \\ -e^{-i\frac{k_x}{2}} \\ e^{-i\frac{k_x+k_y}{2}} \end{pmatrix}, \qquad E = -2\gamma + \lambda ,$$
 (C18)

$$u_{\xi=1,\eta=\pm 1,n=2}(\mathbf{k}) = \frac{1}{2} \begin{pmatrix} \frac{1+\eta}{2} \\ \frac{1-\eta}{2} \cdot e^{i\frac{k_x + k_y}{2}} \end{pmatrix} \otimes \begin{pmatrix} 1 \\ e^{-i\frac{k_y}{2}} \\ e^{-i\frac{k_x + k_y}{2}} \end{pmatrix}, \qquad E = 2\gamma + \lambda.$$
 (C19)

Here  $\eta=\pm 1$  indicates the  $\rho_z=\pm 1$  block,  $\xi=\pm 1$  is the  $C_2$  (=  $S_4^2$ ) eigenvalue of the molecule orbital. One can verify that these solutions satisfy

$$u_{\xi\eta n}(\mathbf{k} + \mathbf{G}) = V^{\dagger}(\mathbf{G})u_{\xi\eta n}(\mathbf{k})$$
 (C20)

where  $V(\mathbf{G})$  is the embedding matrix given in Eq. (C4).

We have chosen  $\gamma \gg \lambda > 0$  such that  $\xi = 1$  states have a large gap  $\sim 4\gamma$  around the  $k_z = 0$  plane provided m = 0. Low energy physics at m = 0 are hence dominated by the  $\xi = -1$  states. We hence project the Dirac term  $m\rho_x\tau_x\sigma_x + 2tk_z\rho_z\tau_z\sigma_z + \mathcal{O}(k_z^2)$  (given below Eq. (C1)) onto the  $\xi = -1$  subspace. We obtain the effective Hamiltonian

$$H^{(\xi=-1)}(\mathbf{k}) = -\lambda \rho_0 \sigma_0 + 2tk_z \rho_z \sigma_x - m \cdot \text{Re}[f(\mathbf{k}) + g(\mathbf{k})] \rho_x \sigma_0 + m \cdot \text{Re}[f(\mathbf{k}) + g(\mathbf{k})] \rho_y \sigma_0 - m \cdot \text{Re}[f(\mathbf{k}) - g(\mathbf{k})] \rho_x \sigma_x + m \cdot \text{Im}[f(\mathbf{k}) - g(\mathbf{k})] \rho_y \sigma_x + \mathcal{O}(k_z^2),$$
 (C21)

where  $f(\mathbf{k})=(1+e^{\mathrm{i}(k_x+k_y)})/4$ ,  $g(\mathbf{k})=(e^{\mathrm{i}k_x}+e^{\mathrm{i}k_y})/4$ . We use  $\rho_z=\pm 1$  for  $\eta=\pm 1$  states and  $\sigma_z=\pm 1$  for n=1,2 states, respectively, in the subspace of  $\xi=-1$ . Clearly, when m=0,  $H^{(\xi=-1)}$  represent two decoupled helical modes (per unit cell), consistent with the topological crystal construction in Fig. 1 of the main text. For  $|m|\ll \gamma$ , we can omit the coupling between  $\xi=\pm 1$  subspaces. Then, the four energy bands in the  $\xi=-1$  subspace are

$$-\lambda \pm 2\sqrt{t^2k_z^2 + m^2|f(\mathbf{k})|^2}, \qquad -\lambda \pm 2\sqrt{t^2k_z^2 + m^2|g(\mathbf{k})|^2} \ . \tag{C22}$$

Since  $|f(\mathbf{k})| = 0$  iff  $k_y = -k_x \pm \pi$ ,  $|g(\mathbf{k})| = 0$  iff  $k_y = k_x \pm \pi$ , a nodal line crossing is formed along the square

$$(\pi, 0, 0) \to (0, \pi, 0) \to (-\pi, 0, 0) \to (0, -\pi, 0) \to (\pi, 0, 0)$$
 (C23)

Being protected the  $P\widetilde{T}$  symmetry, the nodal line is stable against coupling to the  $\xi=1$  subspace. However, we find that the coupling lifts the four-fold degeneracy at X, which is not protected by the single-valued magnetic space group  $P_C4/nbm$ , and eventually deforms the square-shaped nodal line into a circular shape (Fig. 6(c)-(g)).

For later convenience, we also derive the representation of P (Eq. (C6)) and  $S_4$  (Eq. (C10)) at  $\mathbf{k} = 0$  in the  $\xi = -1$  subspace:

$$\mathcal{D}^{(\xi=-1)}(P) = -\rho_x \sigma_0, \qquad \mathcal{D}^{(\xi=-1)}(S_4) = -i\rho_0 \sigma_z. \tag{C24}$$

At  $\mathbf{k} = 0$ , the doubly degenerate energy level  $-\lambda + m$  has P and  $S_4$  eigenvalues 1, 1 and i,  $-\mathbf{i}$ , respectively; and the other doubly degenerate level  $-\lambda - m$  has P and  $S_4$  eigenvalues -1, -1 and i,  $-\mathbf{i}$ , respectively.

The nodal line shrinks as m increases. As shown in Fig. 6, all the high symmetry momenta except  $\Gamma$  remain gapped as m changes from  $0^+$  to values greater than  $2\gamma$ . A level crossing happens at  $\Gamma$  when  $m=2\gamma$ , upon which the nodal line shrinks to zero. We now analyze this level crossing; it may help us understand the topology of the model. Thanks to the  $C_2$  symmetry, the  $\xi=\pm 1$  subspaces are decoupled at  $\Gamma$ . Each of the energy levels  $E=-\lambda\pm 2m$  in the  $\xi=-1$  subspace is a monotonous function of m, hence, provided  $\gamma\gg\lambda>0$ , they do not participate in the level crossing around  $\pm\lambda$  when  $m=2\gamma$ . Thus, we only need to study the  $\xi=+1$  subspace. The effective Hamiltonian on the basis  $u_{\xi=+1,\eta,n}(\mathbf{0})$  reads

$$H^{(\xi=+1)}(\mathbf{k}=0) = \lambda \rho_0 \sigma_0 - 2\gamma \rho_0 \sigma_z + m\rho_x \sigma_0$$
 (C25)

The energy levels  $\lambda + 2\gamma - m$  and  $\lambda - 2\gamma + m$  cross each other at  $m = 2\gamma$ . We also notice that, at  $\mathbf{k} = 0$ , the P (Eq. (C6)) and  $S_4$  (Eq. (C10)) symmetry operators act in the  $\xi = +1$  subspace as

$$\mathcal{D}^{(\xi=+1)}(P) = \rho_x \sigma_0, \qquad \mathcal{D}^{(\xi=+1)}(S_4) = -\rho_0 \sigma_z. \tag{C26}$$

One can immediately observe that the level  $\lambda + 2\gamma - m$  has P and  $S_4$  eigenvalues -1 and 1, respectively, and the level  $\lambda - 2\gamma + m$  has P and  $S_4$  eigenvalues 1 and -1, respectively.

We now calculate the symmetry-based indicators [13, 69, 55] given by P and  $S_4$  eigenvalues:

$$\eta_{4I} = \sum_{\mathbf{k} \in K^8} n_{\mathbf{k}}(P = -1) \mod 4, \qquad (C27)$$

$$z_2 = \sum_{\mathbf{k} \in K^4} \frac{n_{\mathbf{k}}(S_4 = 1) - n_{\mathbf{k}}(S_4 = -1)}{2} \mod 2,$$
(C28)

$$\delta_{2S} = \sum_{\mathbf{k} \in K^4} e^{ik_z} \left( n_{\mathbf{k}} (S_4 = -i) - n_{\mathbf{k}} (S_4 = -1) \right) \mod 2.$$
 (C29)

Here  $K^8=\{(0/\pi,0/\pi,0/\pi)\}$  are the eight inversion-invariant momenta, and  $K^4=\{(0,0,0/\pi),(\pi,\pi,0/\pi)\}$  are the four  $S_4$ -invariant momenta.  $n_{\mathbf{k}}(P=-1), n_{\mathbf{k}}(S_4=\pm 1,\pm \mathrm{i})$  denote the number of occupied levels at  $\mathbf{k}$  that have the corresponding symmetry eigenvalues. For more details, as well as four additional indicators  $(z_{2I,i}, z_{4S,\pi})$  representing 3D Chern numbers, readers may refer to discussions around Eqs. (235) and (270) of the supplementary materials of Ref. [69]. Since  $z_{2I,i}, z_{4S,\pi}$  are always trivial in our model, we do not discuss them further here. Additionally, one need not worry about crossings enforced by the compatibility relations of  $C_2=S_4^2$ , which would invalidate  $z_2,\delta_{4S}$ , because there is no crossing along the high symmetry lines  $\Gamma Z$ , MA, XR. Thus,  $\eta_{4I}, z_2$ , and  $\delta_{2S}$  are all the meaningful indicators given by P and  $S_4$ . Odd  $\eta_{4I}$  and  $\delta_2$  implies existence of Weyl points. In a gapped insulator there must be  $\eta_4 \in \text{even}$ ,  $\delta_{2S}=0$  and

$$P_3 = \frac{\eta_{4I}}{4} = \frac{z_2}{2} \mod 1 \tag{C30}$$

provided all 3D Chern numbers equal to zero.

We now calculate  $\eta_{4I}, z_2, \delta_{2S}$  for our model. Since the  $m \to \infty$  limit must have trivial indicators, we can replace  $n_{\bf k}$  in Eqs. (C27) to (C29) by  $\delta n_{\bf k}$  - the change of  $n_{\bf k}$  with respect to the  $m \to \infty$  limit. According to the discussions around Eq. (C25), the nodal line semi-metal with  $0 < m < 2\gamma$  has

$$\delta n_{\Gamma}(P=1) = 1$$
,  $\delta n_{\Gamma}(P=-1) = -1$ ,  $\delta n_{\Gamma}(S_4=1) = -1$ ,  $\delta n_{\Gamma}(S_4=-1) = 1$ ,  $\delta n_{\Gamma}(S_4=\pm i) = 0$ . (C31)

and hence

$$\eta_{4I} = 3, \qquad z_2 = 1, \qquad \delta_{2S} = 1.$$
(C32)

 $\eta_{4I}=3$  indicates that the considered state must have Weyl points. Similarly,  $\delta_{2S}=1$  also implies that the considered state must have Weyl points. Due to the  $P\widetilde{T}$  symmetry, these Weyl points must be part of nodal lines, which are further pinned in the  $k_z=0$  plane by the glide  $(\widetilde{M}_z=\{m_{001}|\frac{1}{2}\frac{1}{2}0\})$  symmetry. It appears that the indicators only reveal the presence of nodal lines. For negative m, we find

$$-2\gamma < m < 0: \quad \delta n_{\Gamma}(P=1) = 3, \quad \delta n_{\Gamma}(P=-1) = -3, \quad \delta n_{\Gamma}(S_4=1) = -1, \quad \delta n_{\Gamma}(S_4=-1) = 1, \quad \delta n_{\Gamma}(S_4=\pm i) = 0$$

$$\Rightarrow \eta_{4I} = 1, \quad z_2 = 1, \quad \delta_{2S} = 1, \quad (C33)$$

$$-4t + 2\gamma < m < -2\gamma: \quad \delta n_{\Gamma}(P=1) = 4, \quad \delta n_{\Gamma}(P=-1) = -4, \quad \delta n_{\Gamma}(S_4 = \pm 1) = 0, \quad \delta n_{\Gamma}(S_4 = \pm i) = 0$$
  
$$\Rightarrow \eta_{4I} = 0, \quad z_2 = 0, \quad \delta_{2S} = 0.$$
 (C34)

Thus, the state with  $-2\gamma < m < 0$  is a nodal line semi-metal as the  $0 < m < 2\gamma$  case, and the band insulator with  $-4t + 2\gamma < m < -2\gamma$  must have  $P_3 = 0$  according to Eq. (C30).

#### 3. Random fluxes or imaginary hoppings

As pointed out in the main text, one can introduce local gaps to the helical modes that only respect the  $C_4T$  symmetry on average. These gaps localize the low energy states in the bulk and give rise the intrinsic statistical topological insulator (STI) characterized by  $P_3=1/2$ . One choice of the local gap is random flux through the 2a and 2b Wyckoff positions. Consider the m=0 limit, where the low energy Hamiltonian around  $k_z=0$  decomposes into decoupled helical modes (Eq. (C15)). In the xy plane, these helical modes are molecule states localized on the squares centered at the 2a positions. Each molecule has a local Hamiltonian:

$$H^{(loc)}(k_z) = 2\eta t k_z \cdot \tau_z \sigma_z + \begin{pmatrix} 0 & \gamma e^{i\frac{\Phi}{4}} & \gamma e^{-i\frac{\Phi}{4}} & \lambda \\ \gamma e^{-i\frac{\Phi}{4}} & 0 & \lambda & \gamma e^{i\frac{\Phi}{4}} \\ \gamma e^{i\frac{\Phi}{4}} & \lambda & 0 & \gamma e^{-i\frac{\Phi}{4}} \\ \lambda & \gamma e^{-i\frac{\Phi}{4}} & \gamma e^{i\frac{\Phi}{4}} & 0 \end{pmatrix} + \mathcal{O}(k_z^2) , \tag{C35}$$

where  $\Phi$  is a flux passing through the molecule,  $\eta=1,-1$  correspond to the molecule formed by orbitals 1, 2, 3, 4 and 5, 6, 7, 8, respectively. We have dropped the k-dependent phase factors in Eq. (C15), which arise from the plane-wave-like Bloch basis, because we are now studying a local problem. The eigenstates at  $k_z=0$  are identical to those in Eqs. (C16)-(C19) except that the k-dependent phase factors should be omitted here. Then we find that the low energy Hamiltonian in the  $\xi=-1$  and  $\pm 1$ 0 subpaces are

$$H^{(\log,\xi=-1)} = -\lambda \cdot \sigma_0 + 2\eta t k_z \cdot \sigma_x - 2\gamma \sin\frac{\Phi}{A} \cdot \sigma_z + \mathcal{O}(k_z^2)$$
 (C36)

and

$$H^{(\log,\xi=1)} = \lambda \cdot \sigma_0 + 2\eta t k_z \cdot \sigma_x - 2\gamma \cos\frac{\Phi}{4} \cdot \sigma_z + \mathcal{O}(k_z^2)$$
 (C37)

respectively. Clearly, a finite flux will gap the helical modes in the  $\xi = -1$  sector.

We find it is more convenient to add random imaginary part to the  $\gamma$  term (red bonds in Fig. 6(a)). They introduce not only random fluxes, but also random hoping strengths. This disorder term can be written as

$$H^{(\text{dis})} = \sum_{\mathbf{R}} i \left( w_{\mathbf{R},1} c_{\mathbf{R},2}^{\dagger} c_{\mathbf{R},2} + w_{\mathbf{R},2} c_{\mathbf{R},3}^{\dagger} + w_{\mathbf{R},3} c_{\mathbf{R},3}^{\dagger} c_{\mathbf{R},1} + w_{\mathbf{R},4} c_{\mathbf{R},4}^{\dagger} c_{\mathbf{R},3} \right.$$

$$\left. + w_{\mathbf{R},5} c_{\mathbf{R},5}^{\dagger} c_{\mathbf{R}+(010),6} + w_{\mathbf{R},6} c_{\mathbf{R},6}^{\dagger} c_{\mathbf{R},8} + w_{\mathbf{R},7} c_{\mathbf{R},7}^{\dagger} c_{\mathbf{R}-(100),5} + w_{\mathbf{R},8} c_{\mathbf{R},8}^{\dagger} c_{\mathbf{R}-(010),7} \right) + h.c.$$
(C38)

Here  $w_{\mathbf{R},\alpha}$  are quenched gaussian variables satisfying

$$\langle w_{\mathbf{R},\alpha} w_{\mathbf{R}',\beta} \rangle = W^2 \cdot \delta_{\mathbf{R},\mathbf{R}'} \delta_{\alpha\beta} . \tag{C39}$$

W is the parameter controlling the disorder strength. For m=0, we expect the intrinsic STI phase at weak and intermediate W because small random fluxes are able to gap out the helical modes. The  $W\to\infty$  limit must give the trivial Anderson insulator.

## 4. Uniform $C_4T$ -breaking flux patterns

In the last subsection we argued that random local fluxes can gap out the helical modes and drive the system into an intrinsic STI phase. We find that our model could become a clean axion insulator (protected by  $S_4$  or P) in the presence of a properly designed  $C_4T$ -breaking flux pattern.

We assume the translation symmetry and denote the fluxes through the squares centered at  $(\frac{1}{4}, \frac{1}{4}, 0)$ ,  $(\frac{3}{4}, \frac{3}{4}, 0)$ ,  $(\frac{1}{4}, \frac{3}{4}, 0)$ ,  $(\frac{3}{4}, \frac{1}{4}, 0)$  and  $\Phi_A$ ,  $\Phi_B$ ,  $\Phi_C$ ,  $\Phi_D$ , respectively (Fig. 7(a)). We consider two patterns

(I): 
$$\Phi_A = \Phi_B = -\Phi_C = -\Phi_D = \Phi$$
, (C40)

(II): 
$$\Phi_A = -\Phi_B = \Phi, \quad \Phi_C = \Phi_D = 0.$$
 (C41)

Pattern-(I) respects both  $S_4$  and P symmetries, whereas pattern-(II) only respects  $S_4$  but breaks P. We find the corresponding Hamiltonians

$$H^{(I)}(\mathbf{k}) = (m + 2t - 2t\cos k_z)\rho_x\tau_x\sigma_x + 2t\sin k_z\rho_z\tau_z\sigma_z$$

$$+ \gamma\cos\frac{\Phi}{4}(\cos\frac{k_x}{2}\rho_0\tau_x\sigma_0 - \sin\frac{k_x}{2}\rho_0\tau_y\sigma_0 + \cos\frac{k_y}{2}\rho_0\tau_0\sigma_x - \sin\frac{k_y}{2}\rho_0\tau_0\sigma_y)$$

$$+ \gamma\sin\frac{\Phi}{4}(\sin\frac{k_x}{2}\rho_0\tau_x\sigma_z + \cos\frac{k_x}{2}\rho_0\tau_y\sigma_z - \sin\frac{k_y}{2}\rho_0\tau_z\sigma_x - \cos\frac{k_y}{2}\rho_0\tau_z\sigma_y)$$

$$+ \lambda(\cos\frac{k_x}{2}\cos\frac{k_y}{2}\rho_0\tau_x\sigma_x + \sin\frac{k_x}{2}\sin\frac{k_y}{2}\rho_0\tau_y\sigma_y - \sin\frac{k_x}{2}\cos\frac{k_y}{2}\rho_0\tau_y\sigma_x - \cos\frac{k_x}{2}\sin\frac{k_y}{2}\rho_0\tau_x\sigma_y), \qquad (C42)$$

$$\begin{split} H^{(\mathrm{II})}(\mathbf{k}) &= (m+2t-2t\cos k_z)\rho_x\tau_x\sigma_x + 2t\sin k_z\rho_z\tau_z\sigma_z \\ &+ \gamma\cos\frac{\Phi}{4}(\cos\frac{k_x}{2}\rho_0\tau_x\sigma_0 - \sin\frac{k_x}{2}\rho_0\tau_y\sigma_0 + \cos\frac{k_y}{2}\rho_0\tau_0\sigma_x - \sin\frac{k_y}{2}\rho_0\tau_0\sigma_y) \\ &+ \gamma\sin\frac{\Phi}{4}(\sin\frac{k_x}{2}\rho_z\tau_x\sigma_z + \cos\frac{k_x}{2}\rho_z\tau_y\sigma_z - \sin\frac{k_y}{2}\rho_z\tau_z\sigma_x - \cos\frac{k_y}{2}\rho_z\tau_z\sigma_y) \\ &+ \lambda(\cos\frac{k_x}{2}\cos\frac{k_y}{2}\rho_0\tau_x\sigma_x + \sin\frac{k_x}{2}\sin\frac{k_y}{2}\rho_0\tau_y\sigma_y - \sin\frac{k_x}{2}\cos\frac{k_y}{2}\rho_0\tau_y\sigma_x - \cos\frac{k_x}{2}\sin\frac{k_y}{2}\rho_0\tau_x\sigma_y) \;. \end{split}$$
 (C43)

 $\gamma\cos\frac{\Phi}{4}$  replace the  $\gamma$  parameter in Eq. (C1), and the  $\gamma\sin\frac{\Phi}{4}$  terms are new. Symmetry-based indicators  $\eta_{4I}, z_2, \delta_{2S}$  (Eqs. (C27) to (C29) can be easily computed, and they suggest a phase diagram shown in (Fig. 7(b)).  $H^{(I)}$  and  $H^{(II)}$  happen to have the same phase diagram, but their gapless phases are physically different. Gapless phase in  $H^{(I)}$  is a nodal line semi-metal due to the  $\widetilde{M}_z = \{m_{001}|\frac{1}{2},0\}$  symmetry, whereas the gapless phase in  $H^{(II)}$  is a Weyl semi-metal.

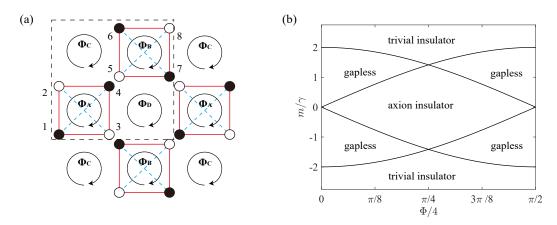


FIG. 7. (a) The position of the four fluxes  $\Phi_A$ ,  $\Phi_B$ ,  $\Phi_C$ ,  $\Phi_D$ . (b) Phase diagram in the presence of  $C_4T$ -breaking flux patterns.  $0 < \gamma < t$  is assumed for simplicity. Patterns (I) and (II) have the same phase diagram, but the gapless phases in the two patterns are physically different.

The phase diagram in Fig. 7(b) may suggest that our model (Eq. (C1)) is relatively "close" to a clean axion insulator. Perturbatively breaking  $C_4T$  symmetry drives the gapless system into a clean axion insulator protected by  $S_4$  or P. However, the intrinsic STI protected by  $C_4T$  does *not* require the existence of (average or exact)  $S_4$  or P.

#### D. Numerical methods and results

### 1. Quasi-1D localization length and the transfer matrix method

The quasi-1D localization length  $\xi_{1D}$  is a commonly used quantity to determine the localization behavior of 2D or 3D systems [58, 59]. We focus on 3D systems in the following, while the 2D case is in principle similar.  $\xi_{1D}(L)$  is defined for a sample with a quasi-1D shape (for example, with geometry  $M \times L \times L$  where  $M \gg L$ ), and reflects the slowest decay rate of energy eigenstates in the longitudinal direction. Since a quasi-1D sample can be viewed as a 1D system with many internal degrees of freedom, and electrons always localize in a 1D system with arbitrary non-zero disorder strength,  $\xi_{1D}(L)$  always converges to a finite value when  $M \to \infty$  with the exception of a perfectly clean sample. The (de)localization of a normal shaped sample, whose sizes in different directions are comparable, can be inferred from the scaling behavior of the dimensionless normalized quasi-1D localization length  $\Lambda(L) = \xi_{1D}(L)/L$ . For a metallic normal shaped sample of size  $L \times L \times L$ , its 3D localization length  $\xi_{3D}(L)$  is much larger than L when L is sufficiently large. If the sample is prepared in a quasi-1D shape with longitudinal size  $M \gg L$ ,  $\xi_{1D}(L)$  grows faster than L, so  $\Lambda(L) \to \infty$  as  $L \to \infty$ . In contrast, for a localized phase,  $\xi_{3D}(L)$  converges to a finite value  $\xi_0$  as  $L \to \infty$ . In this case,  $\xi_{1D}(L)$  also converges to  $\xi_0$  in the large L limit, leading to  $\Lambda(L) \to 0$ . For the critical state,  $\xi_{1D}(L)$  increases linearly with L for large L, meaning that  $\Lambda(L)$  approaches a finite value  $\Lambda_c$  when  $L \to \infty$ .

The transfer matrix method [58] is widely used to numerically compute  $\xi_{1D}(L)$ . A quasi-1D sample is devided into layers normal to the longitudinal direction, with the amplitudes of energy eigenstates on different layers related by the time-independent Schrödinger equation. Specifically, the Hamiltonian of a tight binding lattice model can be written as

$$H = \sum_{ij} t_{ij} c_i^{\dagger} c_j = \sum_{q=-r_1}^{r_2} \sum_{l=1}^{M} \sum_{\alpha,\beta=1}^{s} t_{l\alpha,(l+q)\beta} c_{l\alpha}^{\dagger} c_{(l+q)\beta}$$
(D1)

where i,j denote orbitals, l denotes layers and  $1 \le \alpha, \beta \le s$  denote the s degrees of freedoms within each layer. The condition  $r_1 \le q \le r_2$  implies that orbitals in the lth layer can hop to at most the  $(l-r_1)$ th or  $(l+r_2)$ th layer in one step. Since the transfer matrices have dimensions  $(r_1+r_2)s$  (see below), the division into layers should be carefully designed to minimize  $r_1, r_2$  and s for optimal numerical efficiency. s direction is taken as the longitudianl direction for the lattice model introduced in Sec. C. Each layer consists of two orbitals in one "column" of a square, along with their partners generated by lattice translations in s0, s1 directions. For example, orbitals s3, s3 in Fig. s3 form the next layer. In this setup, s4 and s5 and s5 form the following derivation assumes s6 for simplicity.

The Schrödinger equation  $H|\psi\rangle=E|\psi\rangle$  can be written as

$$\sum_{q=-1}^{1} H_{l,l+q} \vec{\psi}_{l+q} = E \vec{\psi}_{l}$$

$$\implies \vec{\psi}_{l+1} = -H_{l,l+1}^{-1} ((H_{l,l} - E) \vec{\psi}_{l} + H_{l,l-1} \vec{\psi}_{l-1})$$
(D2)

where  $(H_{l,l'})_{\alpha,\beta} = t_{l\alpha,l'\beta}$ , and  $\vec{\psi}_l^T = (\psi_{l,1},\psi_{l,2},\cdots)$  are the amplitudes of an energy eigenstate with energy E in the lth layer. If  $H_{l,l+1}$  is singular, a different layer partition with an invertible  $H_{l,l+1}$  must be used. The relation between amplitudes in adjacent layers is:

where

$$T_{l} = \left[ \frac{-H_{l,l+1}^{-1}(H_{l,l} - E) - H_{l,l+1}^{-1}H_{l,l-1}}{I_{s \times s} 0_{s \times s}} \right]$$
(D4)

is the lth transfer matrix. In a disordered system,  $T_l$ 's contain random elements, and their consecutive product  $O_M = \prod_{l=1}^M T_l$  transforms the amplitudes on the first two layers to those on the last two layers. A theorem by Oseledec [73] guarantees the existence of the limit  $P = \lim_{M \to \infty} (O_M^{\dagger} O_M)^{1/2}$ , whose eigenvalues  $\{\exp(\nu_1), \exp(-\nu_1), \ldots \exp(\nu_s), \exp(-\nu_s)\}$  come in pairs. The positive exponents  $\nu_1 > \ldots > \nu_i > \nu_{i+1} > \ldots > \nu_s > 0$  are called Lyapunov exponents (LEs). An eigenvector  $\vec{\eta_i}$  of P with eigenvalue  $\exp(-\nu_i)$  satisfies  $\|O_M \vec{\eta_i}\|^2 = \|\exp(-M\nu_i)\vec{\eta_i}\|^2$  for sufficiently large M. Therefore, the smallest LE  $\nu_s$  determines the slowest decay rate of energy eigenstates with energy E along the longitudinal direction, and the quasi-1D localization length is defined as  $\xi_{1D} = 1/(\nu_s l_0)$ , where  $l_0 = 4$  for the lattice model denotes the number of layers in a unit cell.

In practice, the matrix  $O_M$  cannot be computed directly. This is because when M is large,  $\exp(M\nu_i) \gg \exp(M\nu_j)$  for  $\nu_i > \nu_j$ , and the smallest LE will quickly pick up large round-off error since most computational resources are consumed by the large LEs. To overcome this difficulty, we perform a QR decomposition after each q transfer matrices are multiplied:

$$Q_j R_j = T_{qj} T_{qj-1} \dots T_{q(j-1)+1} Q_{j-1}$$
(D5)

where  $Q_j^{\dagger}Q_j=I, Q_0=I_{2s\times 2s}$ , and  $R_j$  is upper-triangular. The process is repeated for j=1,...,M/q. During each step, the logarithms of diagonal elements of each  $R_j$  are stored. We point out without proof that [58]

$$\nu_i = \lim_{M/q \to \infty} \frac{1}{M/q - n_0} \sum_{j=n_0+1}^{M/q} \frac{\ln(R_j)_{i,i}}{q}$$
 (D6)

where we have excluded the first  $n_0q$  layers to avoid possible boundary effects.

Eq. (D6) also provides us an unbiased estimation of the numerical precision of LEs: each LE can be viewed as an average of  $M/q-n_0$  random samples, whose standard derivation can be estimated and interpreted as the numerical error of the LE. Prudent readers may suspect that the "random samples"  $\ln{(R_j)}_{i,i}/q$  with close i's might not be independent for small q. In practice, we group up  $r \sim 10$  adjacent "random samples" together and assume that different groups are independent.

We have introduced the method to calculate  $\nu_s$  and its numerical precision  $\delta\nu_s$  for a quasi-1D sample with a given disorder configuration. To further reduce the numerical uncertainty, we take the average of  $\nu_s$  for  $N_D$  different disorder configurations. The averaged  $\bar{\nu_s}$  and its uncertainty is given by

$$\bar{\nu_s} = \frac{1}{N_D} \sum_{k=1}^{N_D} \nu_s^{(k)}, \delta \bar{\nu_s} = \frac{1}{N_D} \sqrt{\sum_{k=1}^{N_D} (\delta \nu_s^{(k)})^2}$$
 (D7)

where  $\nu_s^{(k)}, 1 \leq k \leq N_D$  denotes  $\nu_s$  for the kth disorder configuration. Numerical  $\Lambda$ 's in this paper are obtained by using  $L \leq 40, M = 2.5 \times 10^4, N_D = 16, q = 4, r = 10$  and  $n_0 = 100$ . The precision of  $\Lambda = 1/(\bar{\nu_s} l_0 L)$  reaches  $\delta \Lambda / \Lambda \leq 0.6\%$  for systems with periodic boundary conditions in both y and z directions, and  $\delta \Lambda / \Lambda \leq 1.5\%$  for systems with open boundary condition in z direction and periodic boundary condition in y direction.

# 2. Scaling analysis and Polynomial fitting of $\Lambda$

As mentioned above,  $\Lambda(L)$  converges to a finite value  $\Lambda_c$  when  $L \to \infty$  for a critical state. Therefore,  $\Lambda(L)$  should be scale invariant for large L's at a metal-insulator phase transition point. On the insulating side of the phase transition, the 3D localization length  $\xi_{3D}$  diverges as  $\xi_{3D} \sim \tilde{r}^{-\nu}$ , where  $\tilde{r} = |r - r_c|/r_c$ , r is a tuning parameter controlling the phase transition (not necessarily the disorder strength), and  $r_c$  is the critical value of r. The phase transition is characterized by a universal critical exponent  $\nu > 0$ , which only depends on the universality class. For sufficiently large L,  $\Lambda$  follows the one-parameter scaling law with scaling variable  $L/\xi_{3D}$  [59], which requires that

$$\Lambda(r,L) = f(L/\xi_{3D}(r)) = F(\tilde{r}L^{1/\nu}) \tag{D8}$$

where f is the one-parameter scaling function. However, numerically accessible L's for 3D models are generally not large enough for us to neglect the finite size effects associated to the irrelevant scaling variables in the renormalization group (RG) theory, where the metal-insulator transition is described by a saddle-point fixed point with one relevant scaling variable and multiple irrelevant scaling variables. The relevant scaling variable  $\phi(\tilde{r},L)$  has scaling dimension  $1/\nu>0$ , while the irrelevant scaling variables all have negative scaling dimensions. For simplicity, we neglect all irrelevant variables but the least irrelevant one, i.e., the one with the largest scaling dimension y<0, which is denoted  $\psi(\tilde{r},L)$ . This approximation is justified by a relatively small irrelevant contribution to  $\Lambda$  and a large |y| (see below). Considering the irrelevant contribution and the non-linearality of variables  $\phi$  and  $\psi$  in  $\tilde{r}$ , Eq. (D8) is modified to [60]

$$\Lambda(r,L) = F(\phi(\tilde{r},L), \psi(\tilde{r},L)) \tag{D9}$$

which can be Taylor expanded as

$$\Lambda(r,L) = \sum_{j_1=0}^{n_1} \sum_{j_2=0}^{n_2} a_{j_1,j_2} \phi(\tilde{r},L)^{j_1} \psi(\tilde{r},L)^{j_2}$$
(D10)

where  $\phi(\tilde{r}, L) = u_1(\tilde{r})L^{1/\nu}$ ,  $\psi(\tilde{r}, L) = u_2(\tilde{r})L^{-y}$ . When  $\tilde{r}$  is small,  $u_1(\tilde{r})$  and  $u_2(\tilde{r})$  can be further expanded as

$$u_i(\tilde{r}) = \sum_{j=0}^{m_i} b_{ij}\tilde{r}^j, i = 1, 2$$
 (D11)

Since  $\tilde{r}=0$  corresponds to the phase transition point,  $u_1(0)=0$ , which implies  $b_{10}=0$ . We also require  $a_{10}=a_{01}=1$  to remove the ambiguity when defining  $u_1,u_2$ . Unknown parameters in the above expansion scheme include  $a_{ij},b_{ij},r_c,\nu$  and y, with total number

$$N_p = m_1 + m_2 + (n_1 + 1)(n_2 + 1) + 2$$
(D12)

The phase transition point  $r_c$  and the universal exponent  $\nu$  are obtained by fitting the  $N_P$  parameters to numerical  $\Lambda$ 's using the  $\chi^2$  fitting method, which minimizes the residual

$$\chi^2 = \sum_{j=1}^{N_d} \left(\frac{\Lambda_j - F_j}{\delta \Lambda_j}\right)^2 \tag{D13}$$

where  $j=1,...,N_d$  denotes  $N_d$  data points,  $F_j$  denotes the value obtained from Eq. (D10), and  $\Lambda_j$  and  $\delta\Lambda_j$  denote numerical  $\Lambda$ 's and their numerical error. The goodness of fit P is given by [60]

$$P = 1 - \frac{1}{\Gamma(N_{DOF}/2)} \int_0^{\chi_{min}^2/2} \exp(-t) t^{\frac{N_{DOF}}{2} - 1} dt$$
 (D14)

where  $N_{DOF}=N_d-N_P$ , and  $\chi^2_{min}$  is the minimal value of  $\chi^2$ . P is the probability that  $N_d$  data points randomly sampled from  $F_j$  with standard derivations  $\delta \Lambda_j$  give a larger  $\chi^2$  than  $\chi^2_{min}$ . We require  $P \geq 0.1$  for a fit to be acceptable. To avoid overfitting, we also require  $N_d > 4N_P$  and the irrelevant contribution to  $F(\tilde{r},L)$  (sum of terms with  $j_2 > 0$  in Eq. (D10)) to be small compared with  $F_j$ , which includes both the relevant and irrelevant contributions.

The error bars of the fitting parameters are determined using the Monte-Carlo method. This is done by generating synthetic data sets  $\tilde{\Lambda_j}'$ , which are Gaussian random numbers with expectation values given by fitted  $F_j$ 's, and standard derivations given by  $\delta\Lambda_j$ 's. We then fit Eq. (D10) to these synthetic data sets to obtain additional parameter sets. The degree of certainty of the fitting parameters are estimated as their respective 95% confidence intervals from 1000 different synthetic data sets.

We have focused on the polynomial fitting of Taylor expansions of  $\Lambda(r,L)$  in above discussions. Since  $\Lambda$  is scale invariant at the phase transition point, fittings using Taylor expansions of  $\Lambda,1/\Lambda$  and  $\ln\Lambda$  near the phase transition point are all in principle equivalent, provided that  $\delta\Lambda/\Lambda$  is sufficiently small for the  $\chi^2$  fitting method to be well justified. In practice, one should choose the best fit with an acceptable goodness of fit, low expansion orders, small irrelavent contributions, and good numerical stability. Most of the phase transition points in Fig. 2(d) in the main text are determined by fitting  $\Lambda$ , while some are determined by fitting  $1/\Lambda$ , as will be discussed in the next section.

#### 3. Numerical results

Let us first discuss the Fermi energy used in the calculation of  $\Lambda$ . As mentioned in the main text, we focus on the behavior of the model at the half-filled Fermi energy, with four electrons per unit cell. As discussed in Sec. C 2, this corresponds to  $E_F=-\lambda$  for m=0, and a m-dependent  $E_F$  for  $m\neq 0$ . However, when  $|m|\ll \gamma$ , the m dependence of  $E_F$  arises from couplings between subspaces with different  $C_2$  eigenvalues, which involve high energy bands and is thus very weak. In this work, we keep  $t=2, \gamma=1, \lambda=0.01$  fixed. As shown in Fig. 2(d) in the main text, the intrinsic STI phase occurs only when |m|<0.05. It is explicit to numerically check that under these conditions, the difference between the half-filled Fermi energy (of the clean model)  $E_F$  and  $-\lambda$  satisfies  $|E_F+\lambda|<1.25\times10^{-5}$ , which is much smaller than any of the model parameters. Since such a small difference does not significantly change the phase boundary between the intrinsic STI and metal phases, we use  $E_F=-\lambda=-0.01$  in all numerical calculations for simplicity.

We have shown the raw data and polynomial fitting of  $\Lambda$  used to determine the phase boundary near  $m=0.01, W_{c2}\approx 1.125$  in Fig. 2(c) of the main text. The Taylor expansion orders are chosen as  $\{m_r, n_r, m_i, n_i\} = \{3, 2, 0, 1\}$ .  $N_P=11$  parameters are used to fit  $N_d=96$  data points, yielding  $N_{DOF}=N_d-N_P=85$ . The minimum residual is  $\chi^2_{min}=70.30$ , resulting in  $\chi^2_{min}/N_{DOF}=0.83$  and a goodness of fit P=0.71. The optimal fit gives  $W_{c2}=1.125[1.015, 1.162], \nu=1.40[1.24, 1.56],$  and y=-2.67[-4.07, -1.40], where brackets denote 95% confidence intervals. Notably, the relevant contributions to  $\Lambda$  (red dots) are close to the fitted values (lines with different colors), indicating that the irrelevant contributions are small. This small irrelevant correction, together with a relatively large |y|, justifies neglecting scaling variables more irrelevant than  $\psi$  in Eq. (D9).

To obtain the phase diagram in Fig. 2(d) of the main text, both W and m are used to control the phase transition. Since the models with m>0 and m<0 are not related to each other by symmetry, their phase boundaries must be determined separately. Additionally, it turns out that near some points on the phase boundary, fitting  $1/\Lambda$  is more suitable than fitting  $\Lambda$ . For completeness, here we present examples of fitting. In Fig. 8(a), with m=-0.01 fixed, W controls the phase transition. Polynomial fitting of  $\Lambda$  using  $\{m_r, n_r, m_i, n_i\} = \{3, 2, 0, 1\}$  gives  $W_{c2} = 1.135[0.982, 1.180]$  and  $\nu = 1.48[1.25, 1.77]$  with P=0.96. In Fig. 8(b), W=0.50 is fixed, and m controls the phase transition. Polynomial fitting of  $\Lambda$  with  $\{m_r, n_r, m_i, n_i\} = \{1, 3, 2, 1\}$  gives  $m_c = 0.0255[0.0232, 0.0273]$  and  $\nu = 1.32[1.20, 1.48]$  with P=0.99. We note that another fit with slightly lower expansion order  $\{m_r, n_r, m_i, n_i\} = \{1, 3, 1, 1\}$  may also be considered acceptable (Fig. 8(c)), yielding  $m_c = 0.0271[0.0232, 0.0292], \nu = 1.15[1.08, 1.25],$  and P=0.93. The critical exponent  $\nu$  from this fit is inconsistent with the previously reported value  $\nu = 1.443[1.437, 1.449]$  for 3D Anderson transitions in the unitary universality class. We attribute this discrepancy to large finite size effects, evidenced by the relatively large irrelevant contribution. However,  $m_c$  from Fig. 8(b) and (c) are consistent with each other, suggesting that the estimation of  $m_c$  and the phase boundary is less affected by finite size effects. Finally, Fig. 8(d) shows the phase transition near  $m=0.01, W_{c1}=0.171$ . The fit using  $1/\Lambda$  rather than  $\Lambda$  with expansion orders  $\{m_r, n_r, m_i, n_i\} = \{4, 2, 1, 1\}$  yields  $W_c = 0.171[0.159, 0.184], <math>\nu = 1.32[1.20, 1.45]$  with P=1.00.

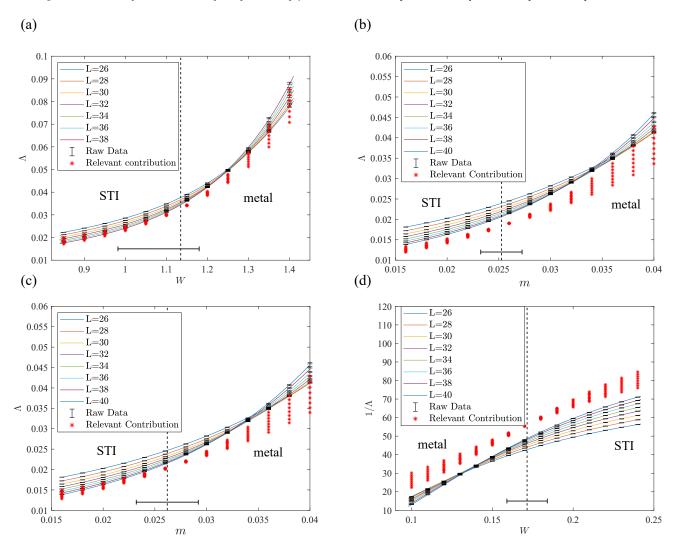


FIG. 8. Examples of other numerical data and polynomial fittings used to determine the phase diagram. Black dots with error bars show raw data, lines with different colors show the polynomial fitting, and red dots show the relevant contributions. (a) m=-0.01 fixed,  $W_{c2}\approx 1.135$  controls the phase transition. (b-c) W=0.50 fixed, m controls the phase transition. (b) and (c) use same raw data but different expansion orders. Despite the discrepancy of the critical exponent  $\nu$  as explained in the paragraph, their  $m_c$ 's are consistent with each other. (d) Polynomial fitting of  $1/\Lambda$  with m=0.01 fixed, and  $W_{c1}\approx 0.171$  controls the phase transition.

# **E.** Generalization to $(C_2T)^2 = -1$ symmetry

Now, we generalize our discussion to  $(C_2T)^2 = -1$  symmetry following the topological crystal method. Since  $C_2T$  is an anti-unitary symmetry squaring to -1, it can also protect Kramers' pairs and forbid the opening of symmetric gaps, ruling out the existence of certain clean TCIs. Consider the topological crystal illustrated in Fig. 9(a), which consists of layers of Chern insulators with the same Chern number C. There are |C| pairs of chiral and anti-chiral modes on each  $C_2T$  axis. If C is even, a  $C_2T$ -symmetric gap is allowed on each  $C_2T$  axis due to the net chirality, resulting in a layered Chern insulator with even 3D Chern number  $C \in 2\mathbb{Z}$ . In contrast, when C is odd, Kramers' degeneracy forbids the opening of  $C_2T$ -symmetric gaps on the  $C_2T$  axes, so layered Chern insulators with odd 3D Chern numbers are forbidden by exact  $C_2T$  symmetry. Introducing disorder on the hinges which breaks  $C_2T$  exactly but preserves it on average will lift the Kramers' degeneracy and allow the  $C_2T$  axes with odd C be localized. We have assumed the normals of layered Chern insulators to be  $\pm \mathbf{e}_y$  in above discussions, while decorations of Chern insulators with normals  $\pm \mathbf{e}_x$  can be made similarly, offering two 3D Chern numbers  $C_x$ ,  $C_y$  in total. Therefore, breaking  $(C_2T)^2 = -1$  symmetry from exact to average enriches the classification of layered Chern insulators from  $2\mathbb{Z} \times 2\mathbb{Z}$  to  $\mathbb{Z} \times \mathbb{Z}$ , with  $C_x \in odd$  or  $C_y \in odd$  cases being intrinsic STIs.

Similarly, consider the topological crystal illustrated in Fig. 9(b), which consists of layers of Chern insulators with opposite Chern numbers C and -C for adjacent layers. The bubble equivalence illustrated in Fig. 9(c) adiabatically changes C by  $\Delta C=2n$  without breaking the  $C_2T$  symmetry, making  $C\in even$  equivalent to C=0, and  $C\in odd$  equivalent to C=1. Since C=0 is obviously trivial, we only have to consider the C=1 case. When  $(C_2T)^2=-1$  is exact, there is one pair of chiral and anti-chiral states on each  $C_2T$  axis, and the Kramers' degeneracy forbids the opening of a symmetric gap as discussed above. When average  $C_2T$  preserving disorder is introduced on the hinges, the  $C_2T$  axes can be localized, while the Chern insulators remain robust. The disordered construction resembles the one illustrated in Fig. 1(a) of the main text and forms an axion STI with  $\bar{\theta}=\pi$ . Therefore, average  $C_2T$  symmetry with  $(C_2T)^2=-1$  can also protect intrinsic axion STIs with a  $\mathbb{Z}_2$  invariant similar to the  $(C_4T)^4=1$  symmetry.

In summary, average  $(C_2T)^2 = -1$  symmetry protects a  $\mathbb{Z} \times \mathbb{Z} \times \mathbb{Z}_2$  STI classification, where the first two topological indices  $C_{x,y}$  denote 3D Chern numbers along x and y directions, and the third one  $\delta$  indicates axion STI when  $C_x = C_y = 0, \delta = 1$ . Since states denoted by  $\{C_x, C_y, \delta\} = \{2m, 2n, 0\}$  are extrinsic STIs, the classification of intrinsic STIs protected by average  $(C_2T)^2 = -1$  symmetry is  $\mathbb{Z}_2 \times \mathbb{Z}_2 \times \mathbb{Z}_2$ .

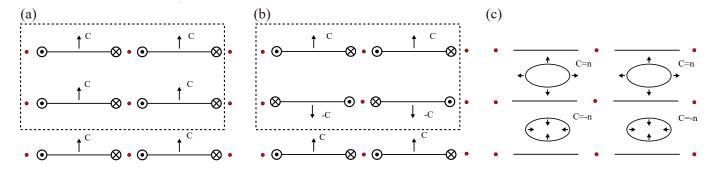


FIG. 9. Topological crystals with  $(C_2T)^2=-1$  symmetry. Red dots show the  $C_2T$  axes, which are occupied by intersecting hinges of Chern insulators. The dashed boxes show unit cells. (a) The topological crystal for layered Chern insulators. Those with  $C\in odd$  can be insulating only in presence of disorder. (b) The topological crystal with opposite Chern numbers for adjacent layers. The C=1 case become an intrinsic axion STI when average  $C_2T$  preserving disorder is introduced on the hinges. (c) By creating  $C_2T$ -symmetric Chern bubbles, a  $\Delta C=2n$  change can be realized adiabatically for the topological crystal illustrated in (b).